



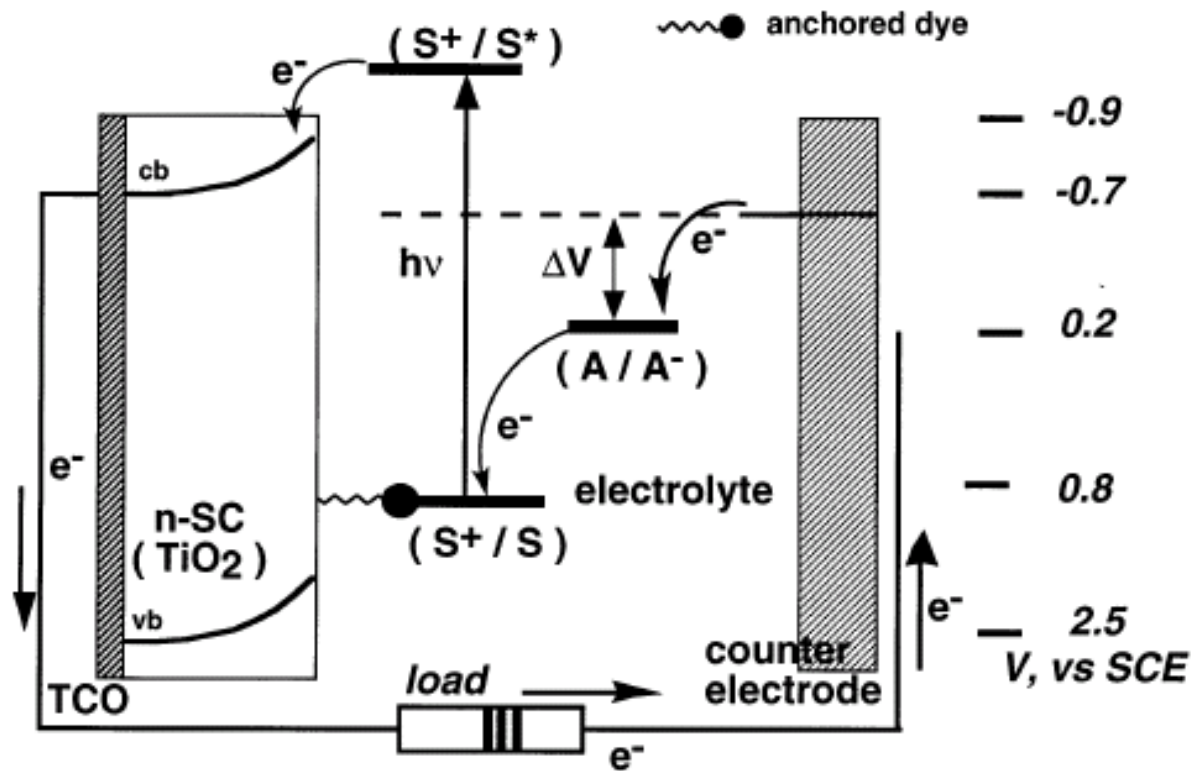
# Dye Sensitized Solar Cells based on Titania Nanomaterials

**F. N. Castellano**



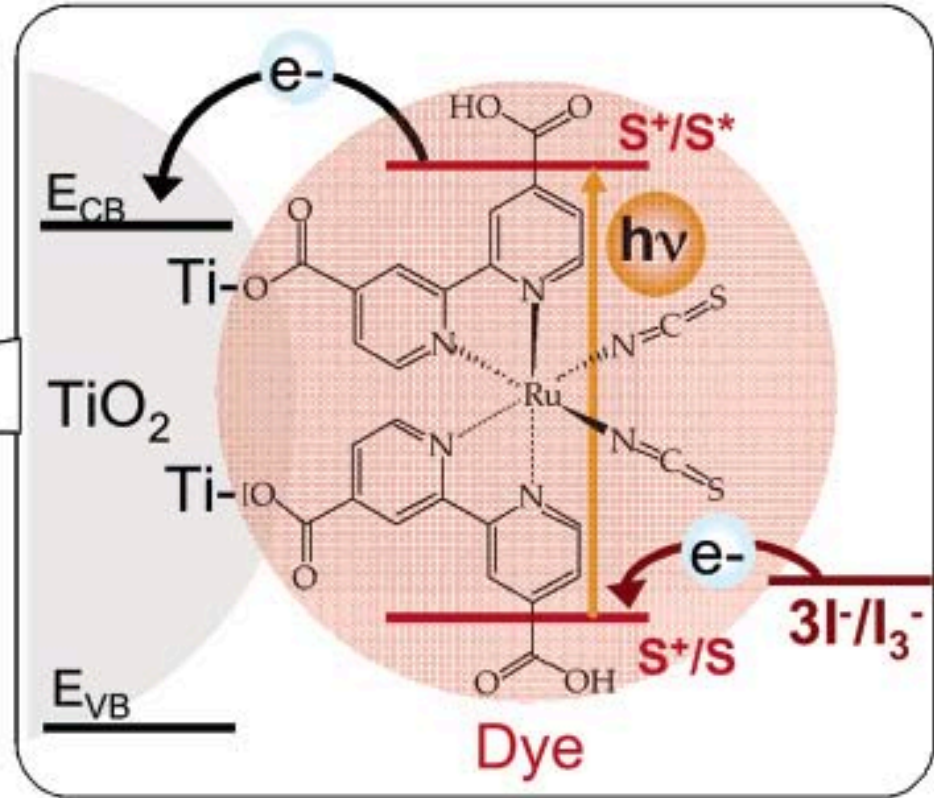
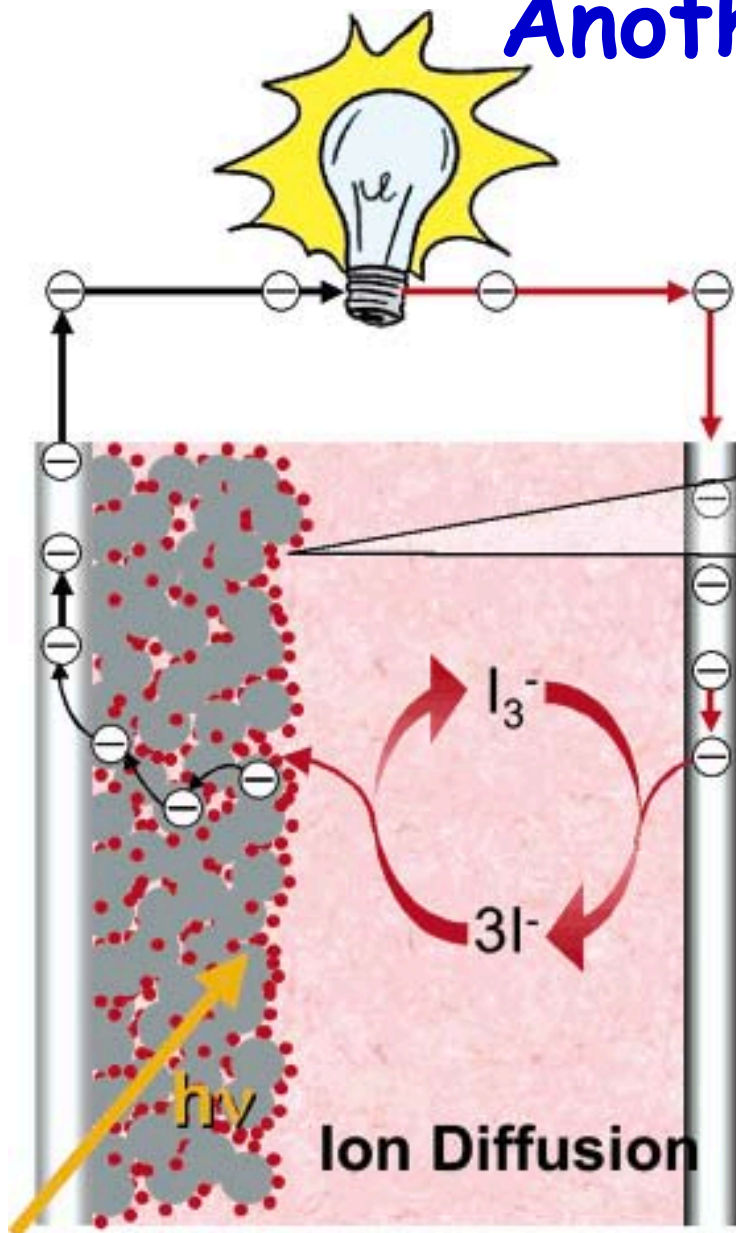
# Metal Oxide Dye Sensitized Solar Cells

## Principles of operation of dye-sensitized solar cell

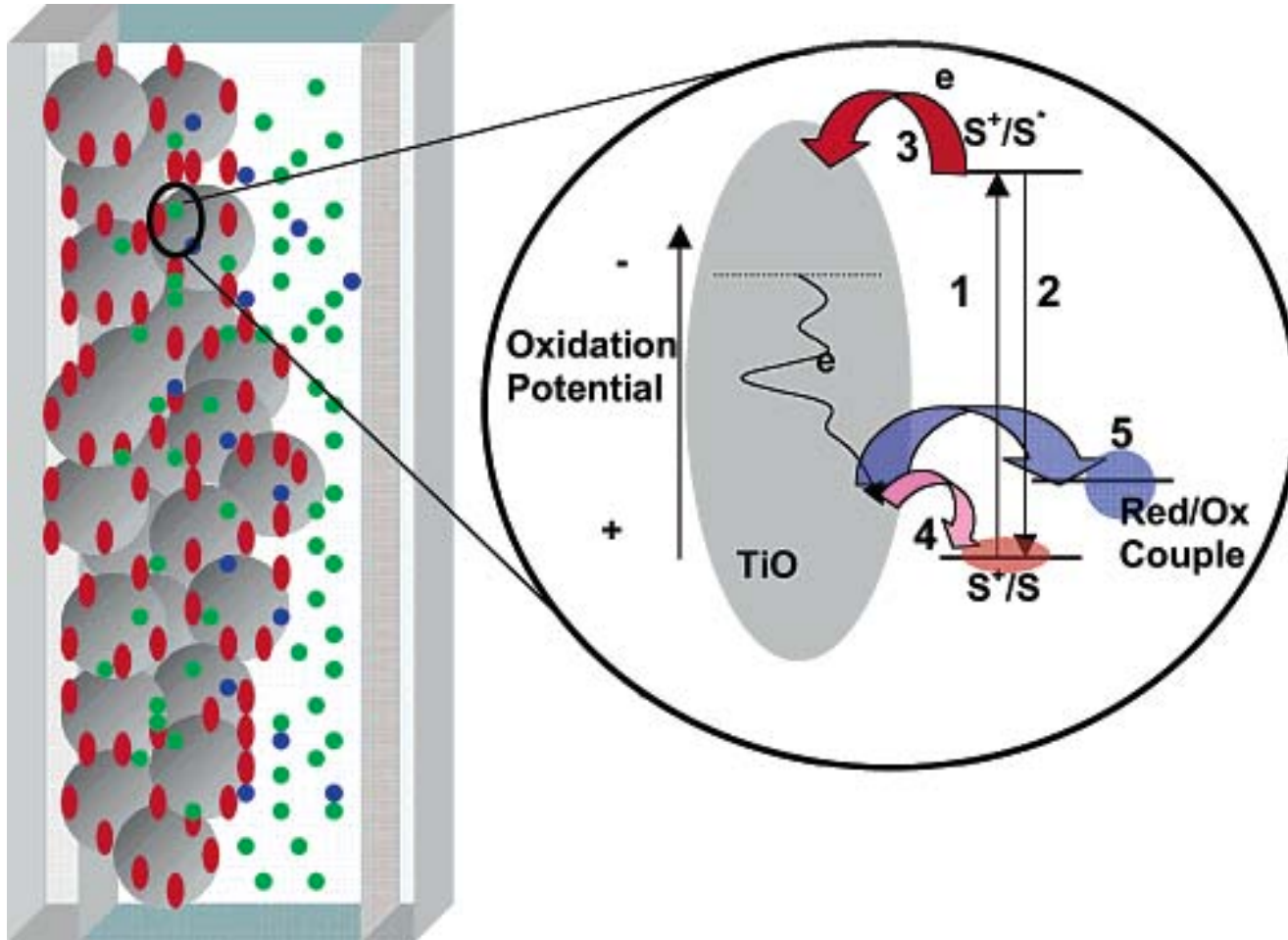


K. Kalyanasundaram & M. Gratzel *Coord. Chem. Rev.* **1998**, 177, 347-414

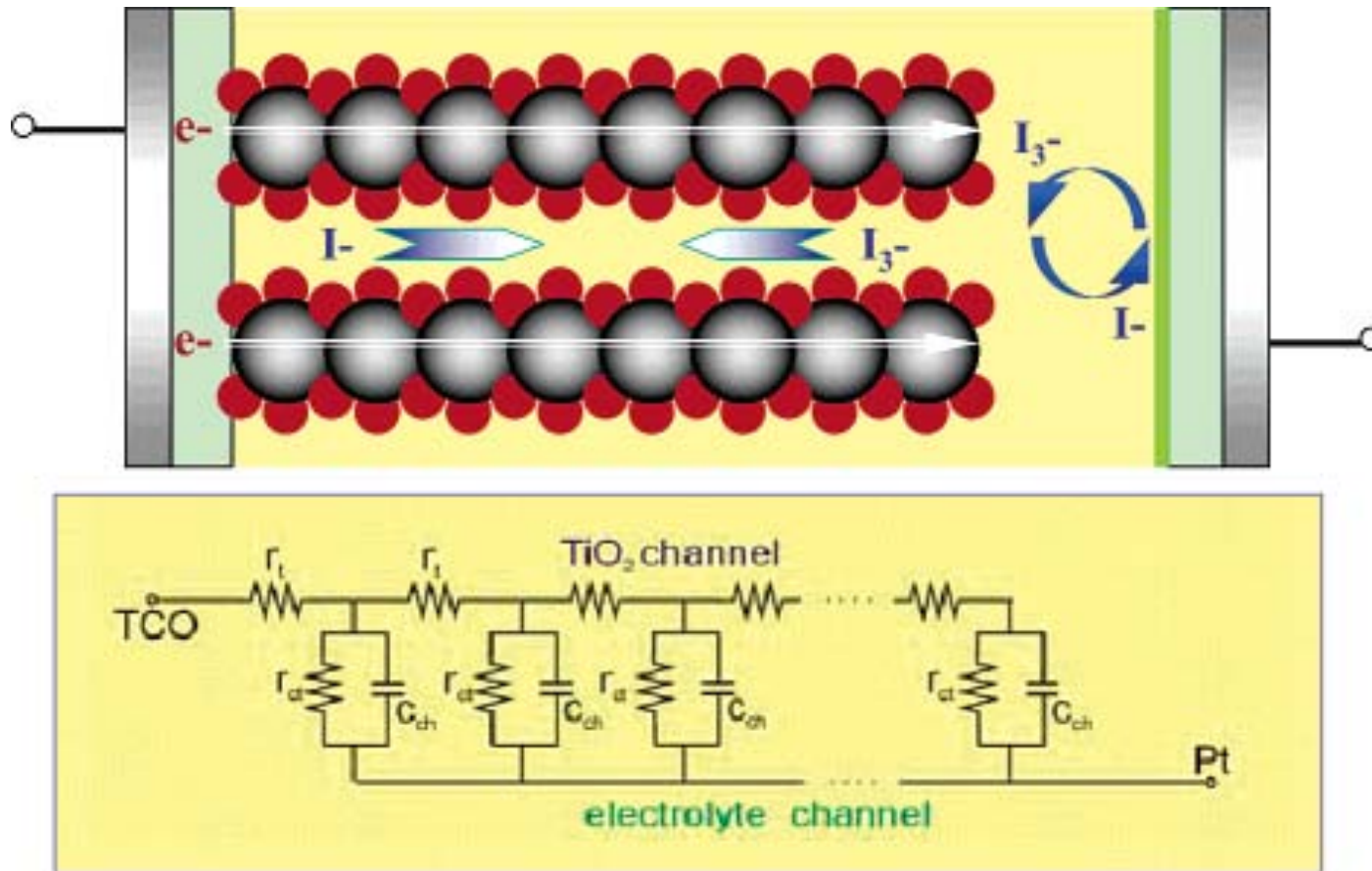
# Another Cartoon



# ...Yet Another Cartoon



# Long Diffusion Distances are Necessary



1. FTO/TiO<sub>2</sub> interface; 2. TiO<sub>2</sub>/electrolyte interface; 3. Electrolyte/Pt interface.

# TiO<sub>2</sub> Nanoparticle Paste Preparation

Mix 37 ml of Ti-(*O*i**-Pr)<sub>4</sub> and 10 ml of *i*-PrOH  
in an addition funnel



Add the mixture to glacial acetic acid (250ml) + H<sub>2</sub>O (80 ml)  
pre-cooled to 0 °C



Stir the solution at 80 °C for 8 hrs



Sonicate in a cell disrupter



Autoclave for 8 hrs at 230 °C



Sonicate in a cell disrupter

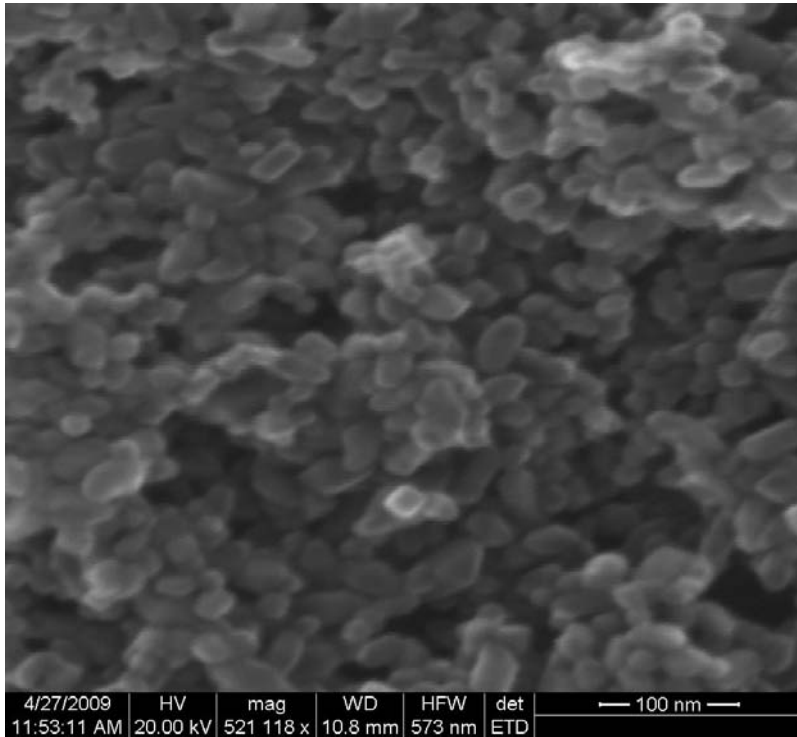


Concentrate the paste to 150 g/L  
or 12 wt % with respect to weight of TiO<sub>2</sub>

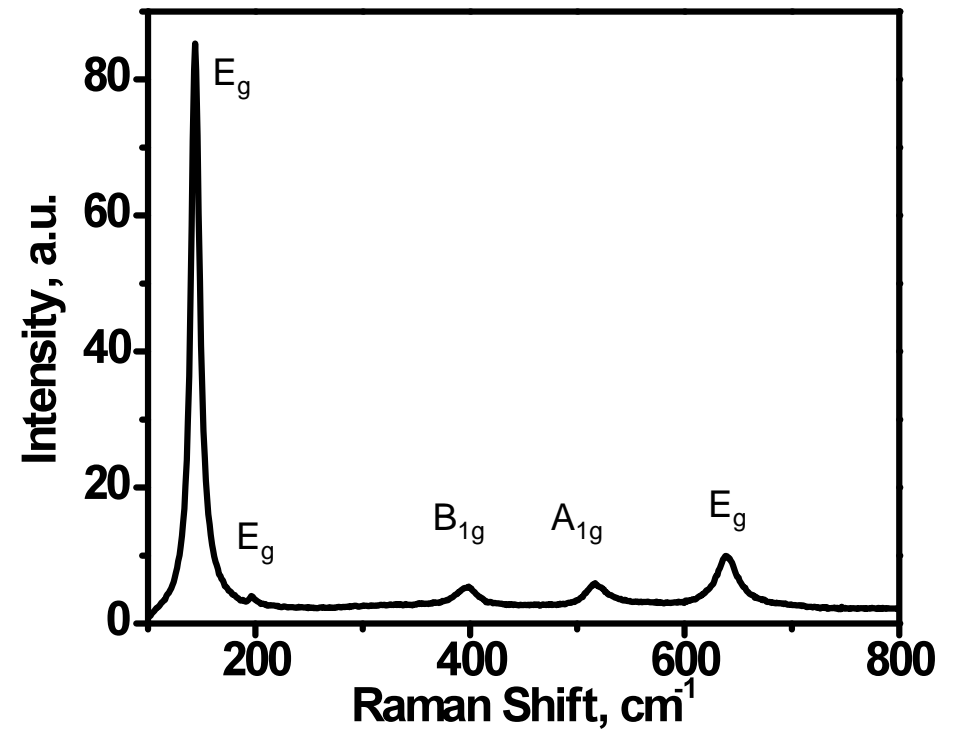


Add hydroxypropyl cellulose to 6 % wt.,  
stir vigorously for 24 hrs

# Characterization of TiO<sub>2</sub> Nanoparticles



SEM image of TiO<sub>2</sub> nanoparticles



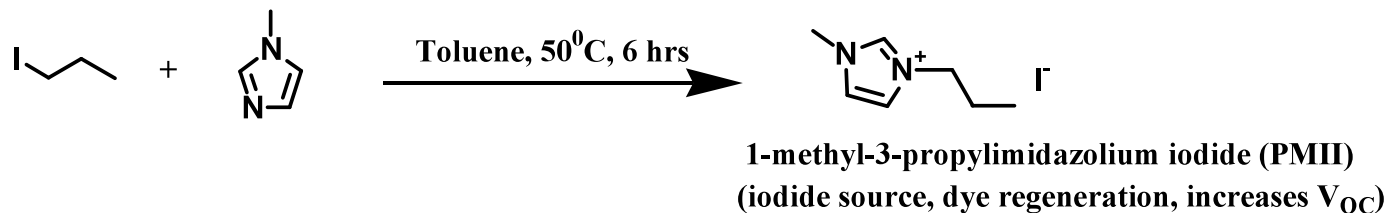
Raman spectrum of TiO<sub>2</sub> film, excitation at 785 nm

# Structure/Function Considerations in Sensitizer Design

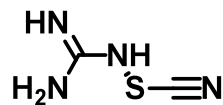
- Strong light absorption over a broad spectral range extending into the near-IR
- Proper alignment of molecular energy levels to ensure regenerative behavior
- Metal oxide surface anchoring moiety (such as COOH)
- Long term photochemical stability
- Long term thermal stability
- Compatible with polymer gel electrolytes
- High throughput chemical synthesis (microwave assisted chemistry desirable)
- Color tunable molecules for niche applications



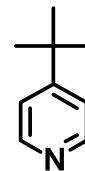
# Various Redox Electrolyte Components



*Tetrahedron* **2003**, *59*, 2253-2258; *J. Org. Chem.* **2002**, *67*, 3145-3148



**guanidine thiocyanate**  
(NCS ligand source, dye repair?)



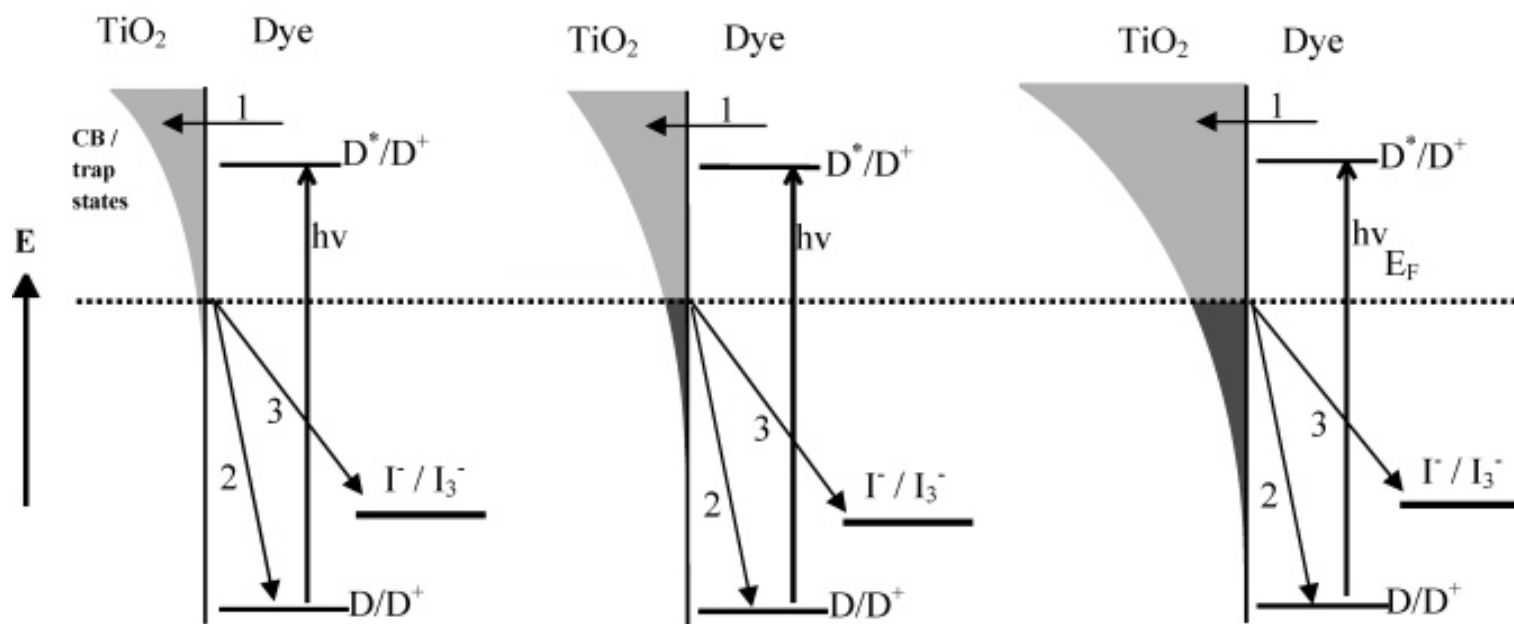
**4-tert-butylpyridine**  
(tunes CB potential to more negative potentials, increases  $V_{OC}$ )

**LiI**  
(tunes CB potential to more positive potentials ( $Li^+$ ),  
decreases  $V_{OC}$ , iodide source, dye regeneration )

**I<sub>2</sub>**  
(iodine source, dye regeneration)

1. Kroeze J. E. *et. al. J. Am. Chem. Soc.* **2006**, *128*, 16376-16383
2. Cameron P. J. *et. al. J. Phys. Chem. B* **2005**, *109*, 930-936
3. Zhang Z. *et. al. Adv. Funct. Mater.* **2008**, *18*, 341-346

# Influence of Electrolyte Composition on Density of CB/Trap States in TiO<sub>2</sub>



## Electrolyte B: No Li<sup>+</sup>

- Slow Electron Injection (1)
- Slow Charge Recombination rates (2) & (3)

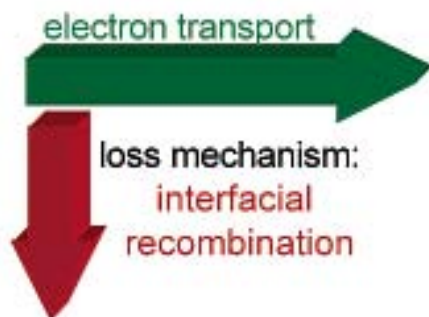
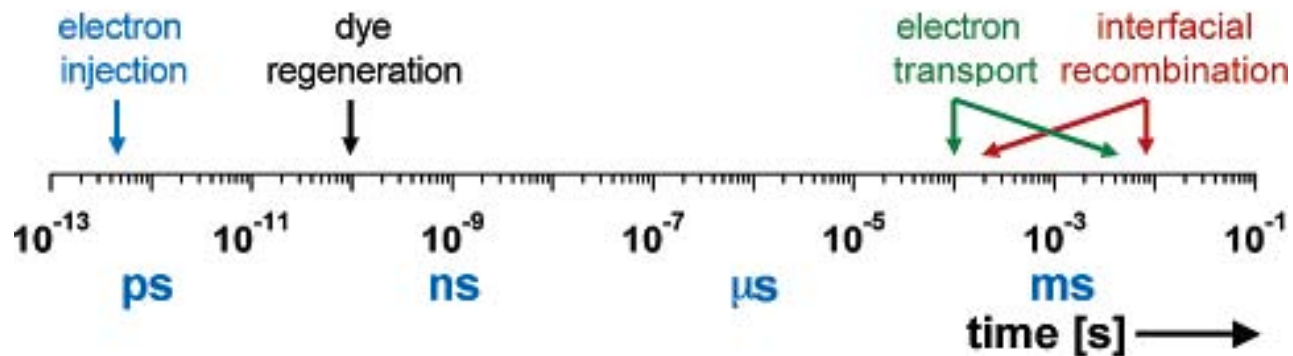
## Electrolyte A: Both Li<sup>+</sup> and 4-tert-butyl pyridine

- Intermediate Electron Injection rate (1)
- Intermediate Charge Recombination rates (2) & (3)

## Electrolyte C: No 4-tert-butyl pyridine

- Fast Electron Injection rate (1)
- Fast Charge Recombination rates (2) & (3)

## Dynamic Competition



Competition  $\Rightarrow$

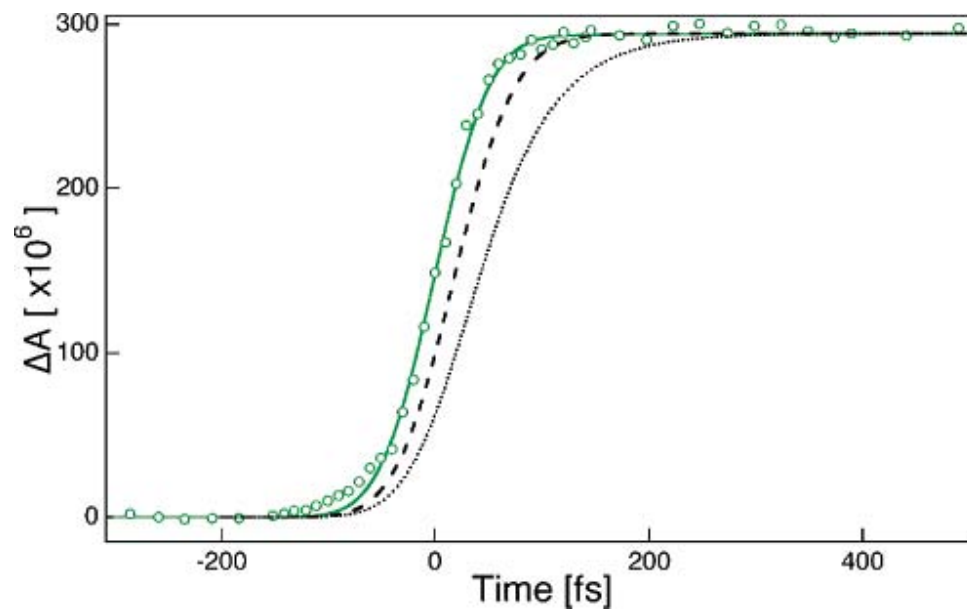
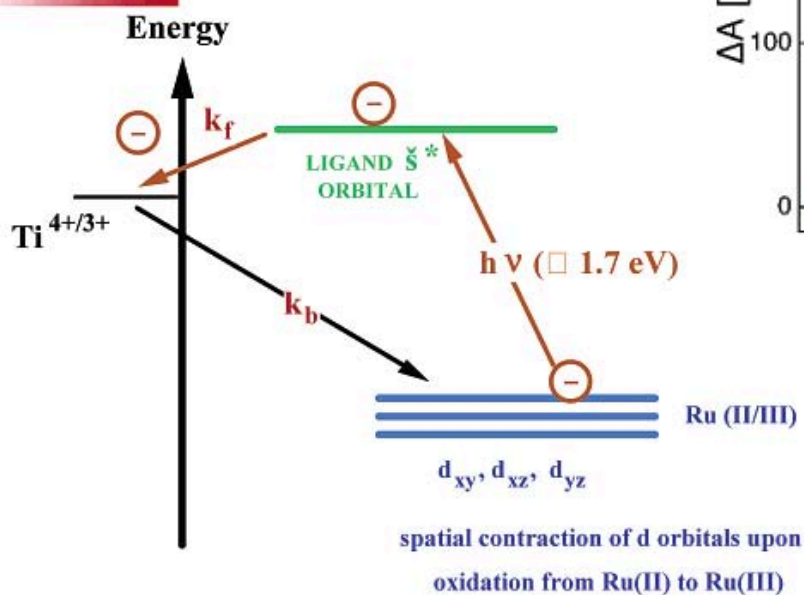
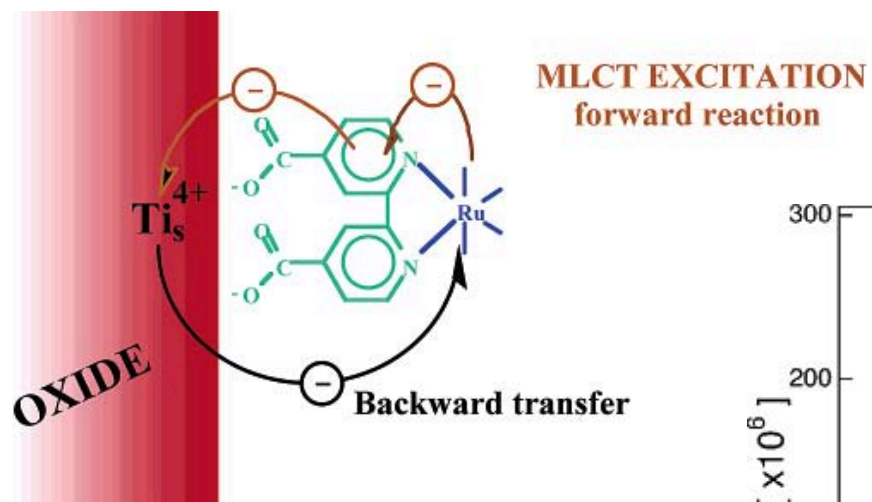
Electron diffusion length

$$L_n = \sqrt{D_n \cdot \tau_n}$$

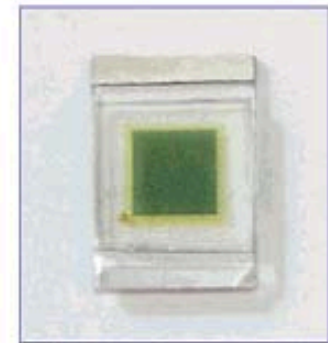
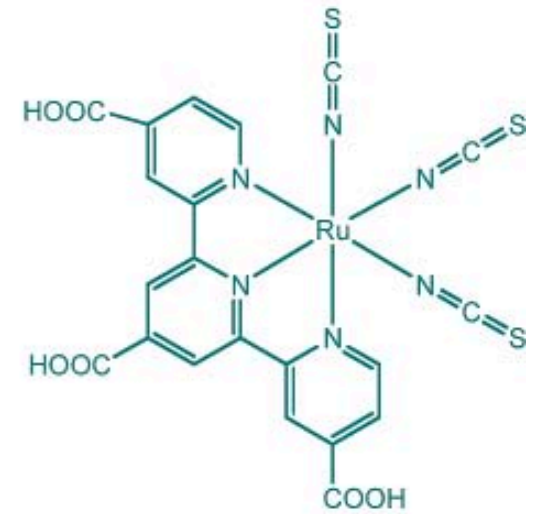
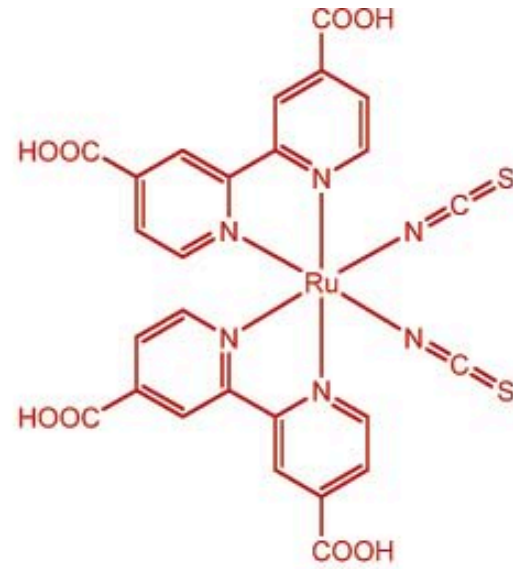
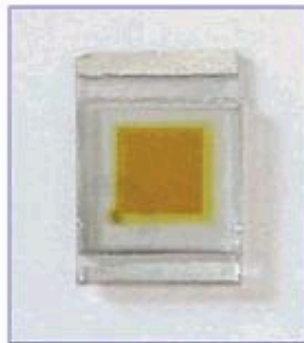
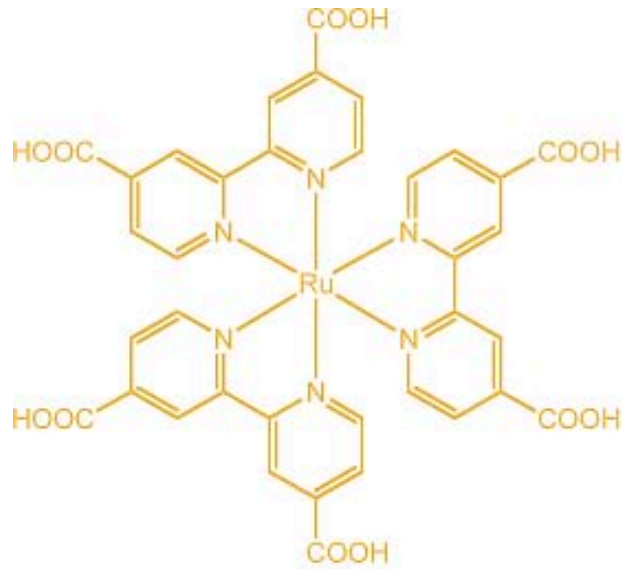
$\tau_n$ : electron lifetime

$D_n$ : electron diffusion coefficient

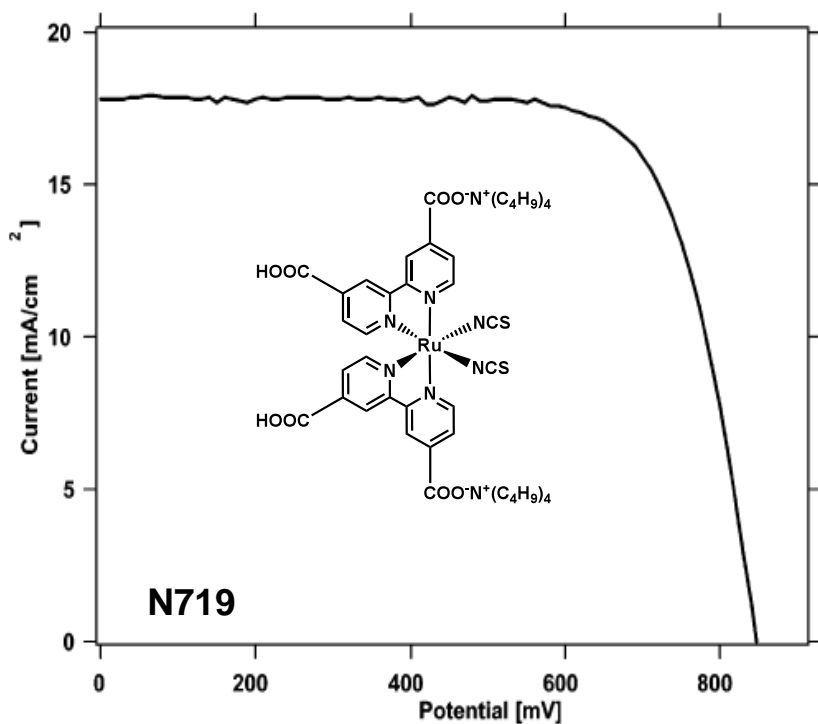
# Ultrafast Injection Kinetics



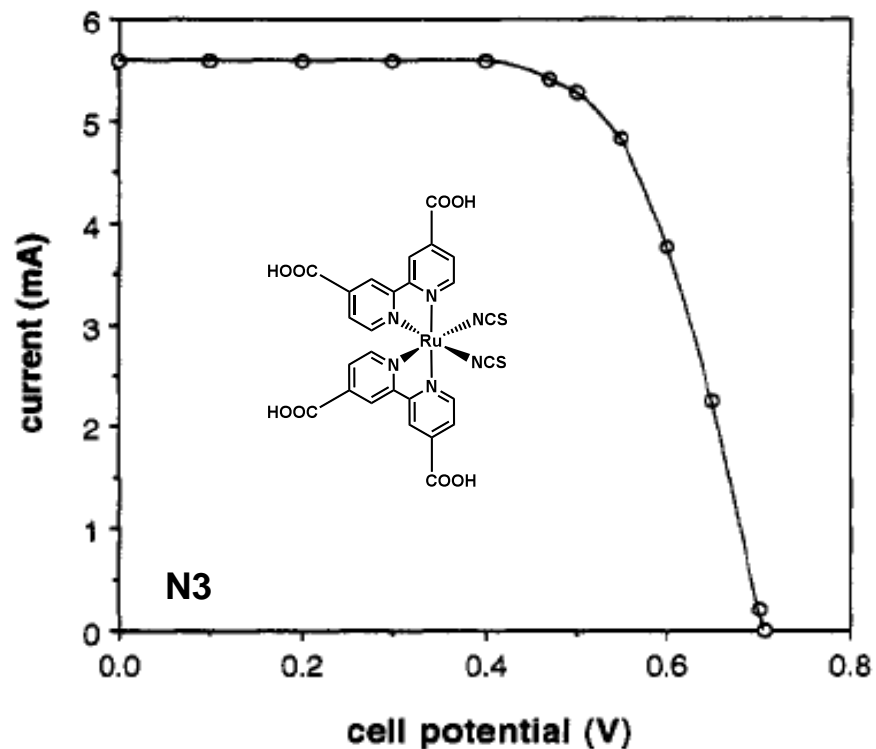
# Operational DSSCs



# State-of-the-Art Mesoscopic Dye-Sensitized Solar Cells



$J_{SC} = 17.73 \text{ mA/cm}^2$   
 $V_{OC} = 846 \text{ mV}$   
 $FF = 0.745$   
 $\text{Efficiency} = 11.18 \%$

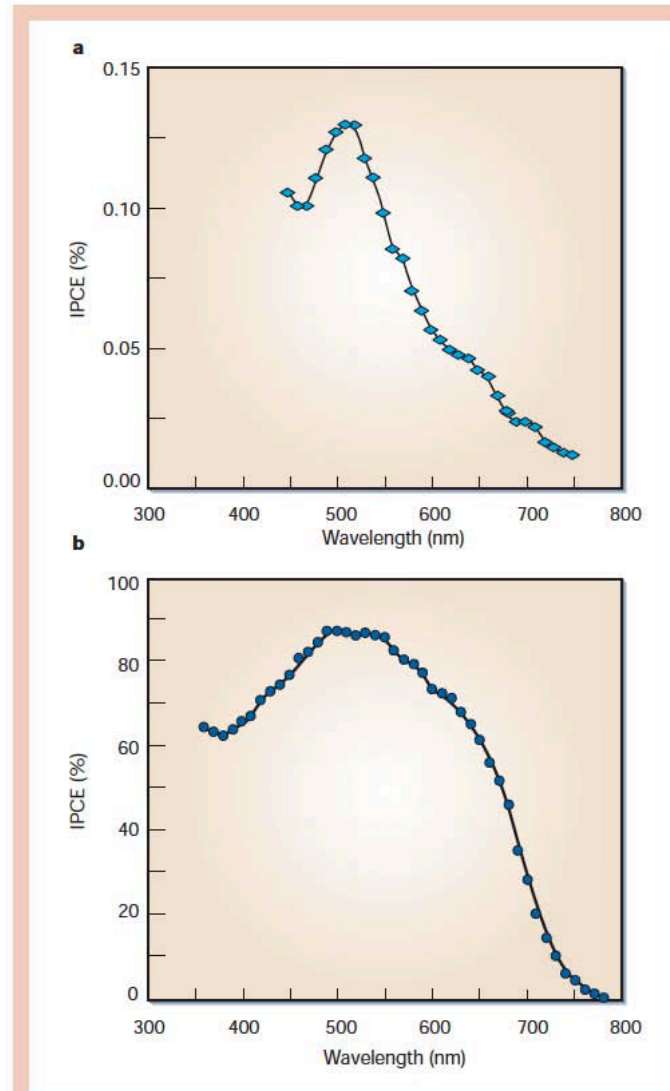


$J_{SC} = 18.2 \text{ mA/cm}^2$   
 $V_{OC} = 720 \text{ mV}$   
 $FF = 0.730$   
 $\text{Efficiency} = 10.00 \%$

Nazeeruddin M. K. *et. al. J. Am. Chem. Soc.* **1993**, *115*, 6382-6390

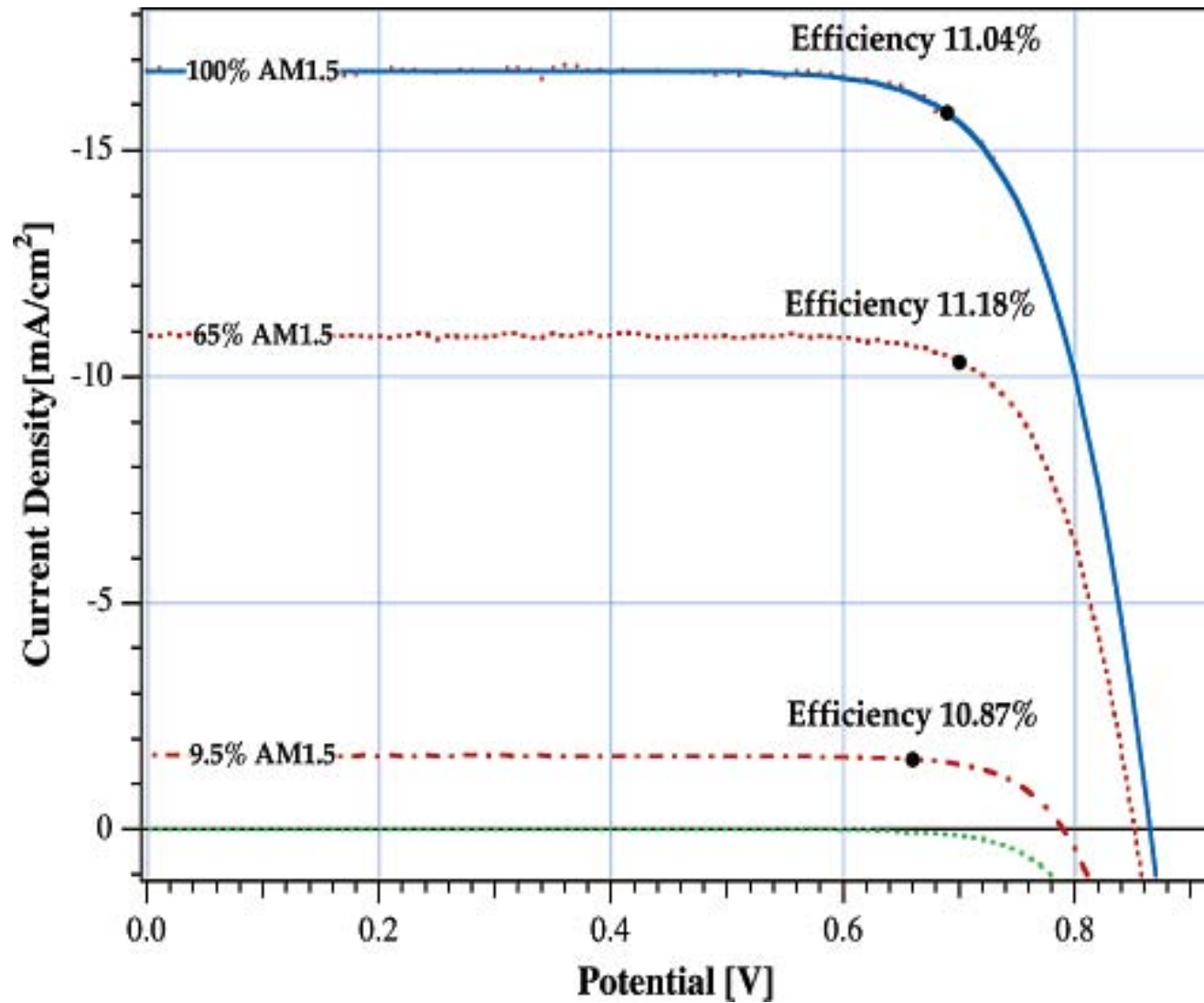
Nazeeruddin M. K. *et. al. J. Am. Chem. Soc.* **2005**, *127*, 16835-16847

# Photoaction - Single Crystal $\text{TiO}_2$ vs. Mesoscopic $\text{TiO}_2$



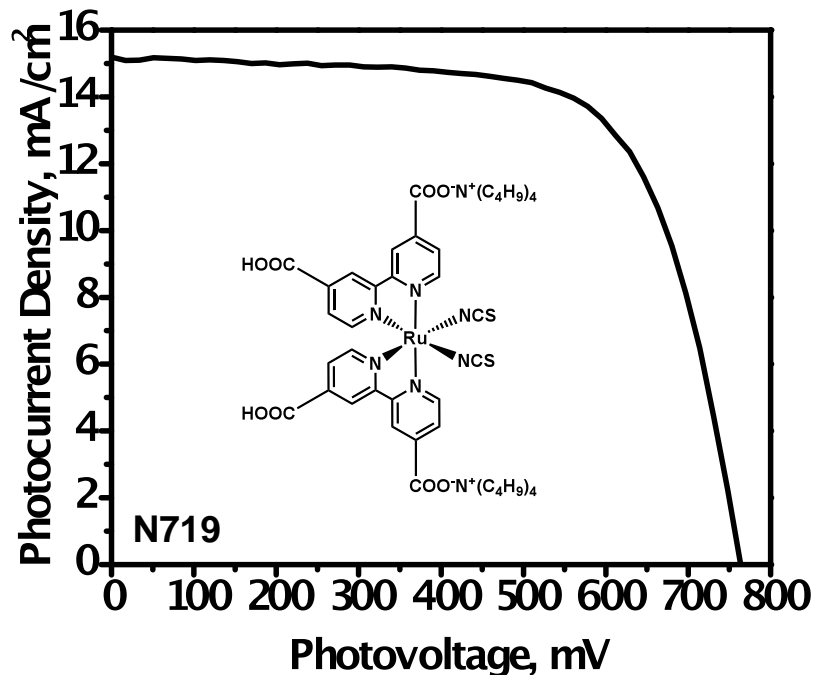
**Figure 5** The nanocrystalline effect in dye-sensitized solar cells. In both cases,  $\text{TiO}_2$  electrodes are sensitized by the surface-anchored ruthenium complex  $\text{cis-RuL}_2(\text{SCN})_2$ . The incident-photon-to-current conversion efficiency is plotted as a function of the excitation wavelength. **a**, Single crystal system cut in the (101) plane

# Present DSSC Efficiency Record

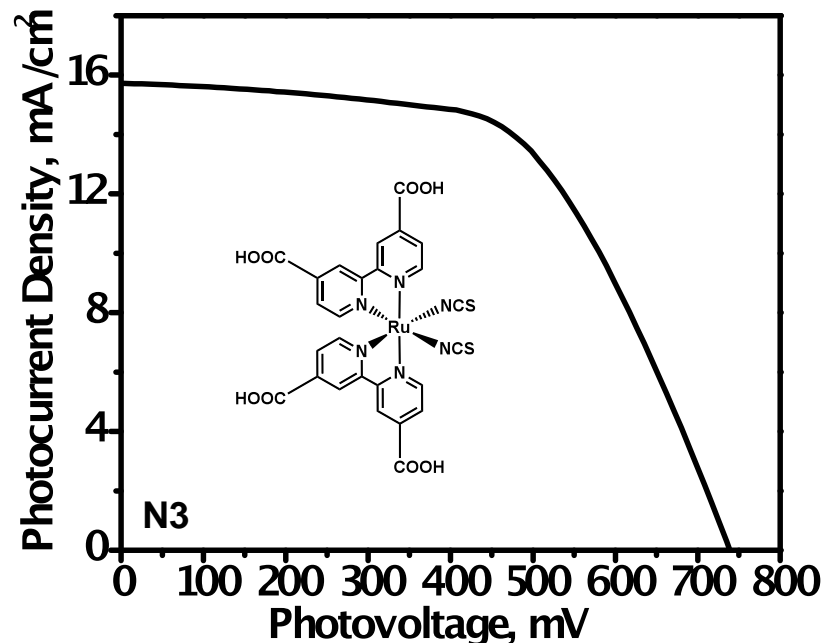




# Our Best Operational Devices To Date



$J_{SC} = 15.2 \text{ mA/cm}^2$   
 $V_{OC} = 763 \text{ mV}$   
 $FF = 69 \%$   
 $\text{Efficiency} = 8.0 \%$



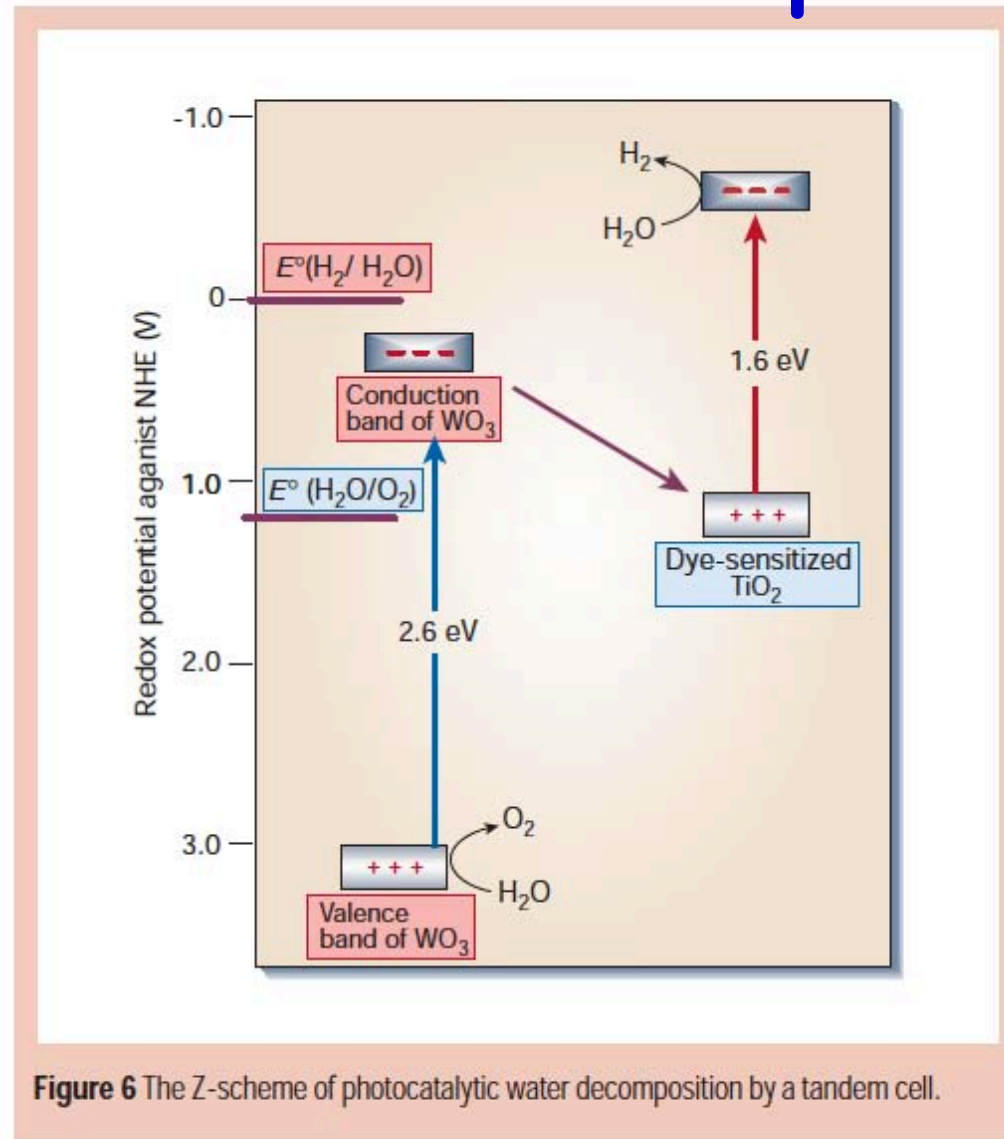
$J_{SC} = 15.7 \text{ mA/cm}^2$   
 $V_{OC} = 739 \text{ mV}$   
 $FF = 58 \%$   
 $\text{Efficiency} = 6.7 \%$

**Electrolyte:** 0.1 M Lil, 0.05 M I<sub>2</sub>, 0.6 M 1-methyl-3-*n*-propylimidazolium iodide, 0.1 M guanidine thiocyanate, 0.5 M 4-*tert*butyl-pyridine in CH<sub>3</sub>CN. Lil concentration was varied as shown

**Device active area:** 0.25 cm<sup>2</sup>. Films sintered at 500 °C for 30 min., sensitized 48 hrs.

TiO<sub>2</sub> film thickness: 12 μm. Transparent paste only. No TiCl<sub>4</sub> treatment!

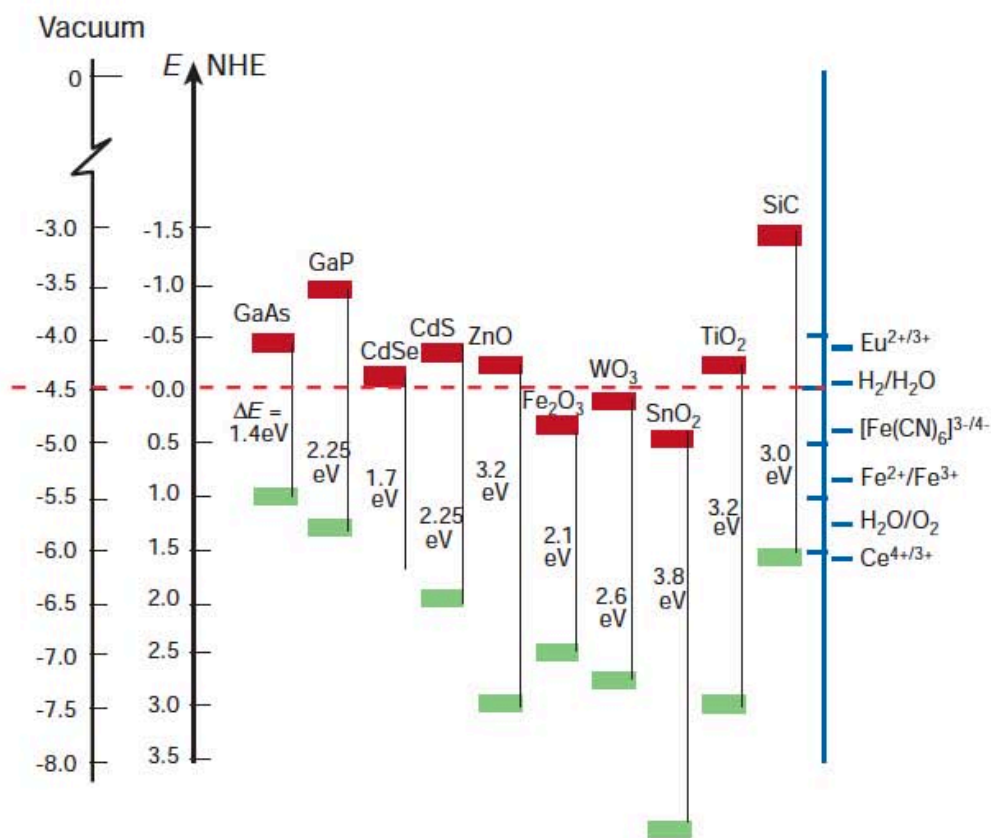
# Solar Fuels Integration - Tandem Cells for Water Splitting



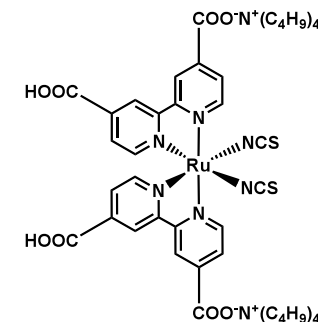
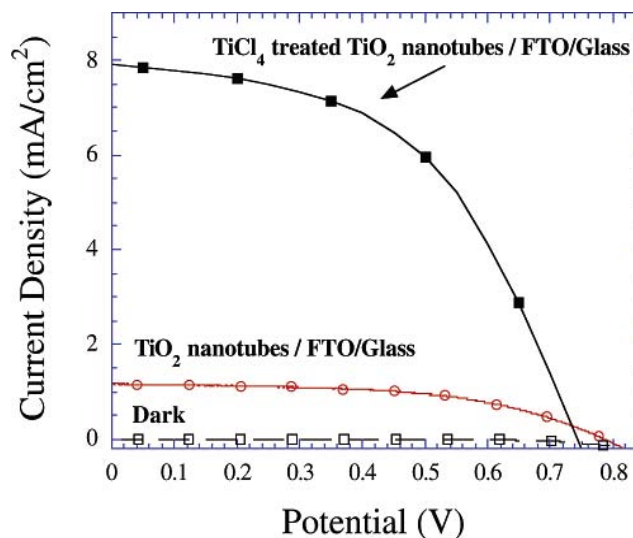
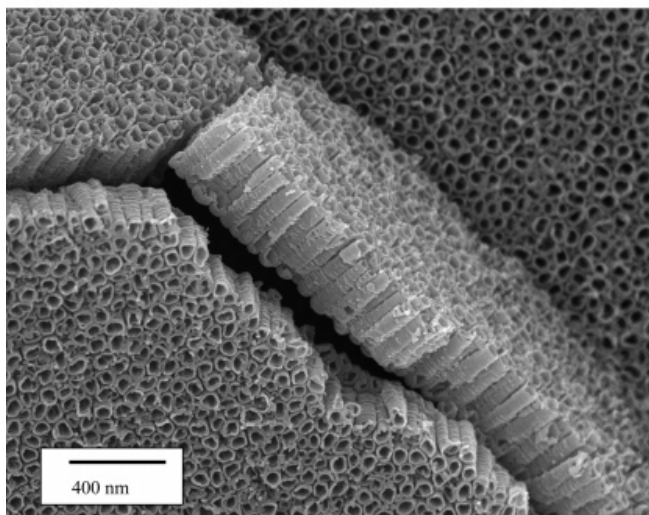
**Figure 6** The Z-scheme of photocatalytic water decomposition by a tandem cell.

# Semiconductor Material Selection

**Figure 2** Band positions of several semiconductors in contact with aqueous electrolyte at pH 1. The lower edge of the conduction band (red colour) and upper edge of the valence band (green colour) are presented along with the band gap in electron volts. The energy scale is indicated in electron volts using either the normal hydrogen electrode (NHE) or the vacuum level as a reference. Note that the ordinate presents internal and not free energy. The free energy of an electron-hole pair is smaller than the band gap energy due to the translational entropy of the electrons and holes in the conduction and valence band, respectively. On the right side the standard potentials of several redox couples are presented against the standard hydrogen electrode potential.

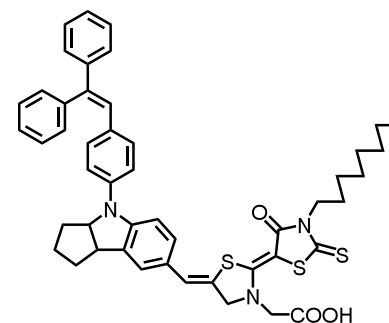
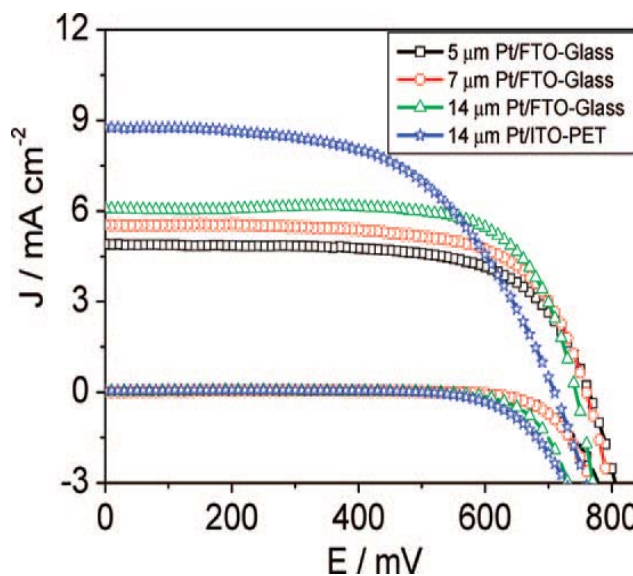
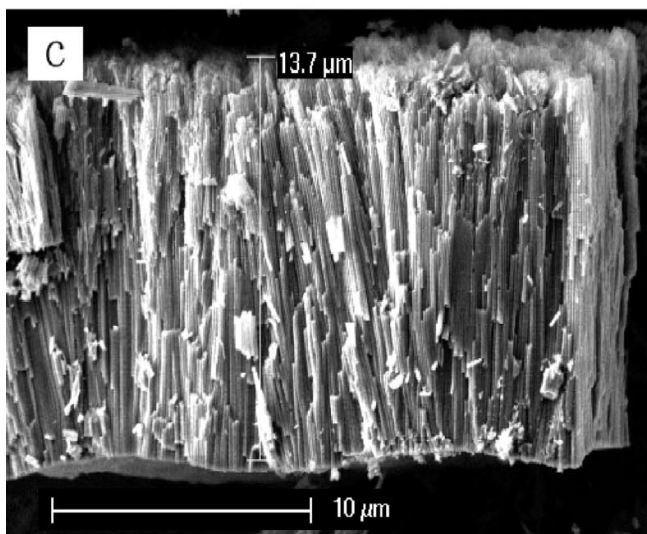


# TiO<sub>2</sub> Nanotube-based DSSCs: Current State



Dye: N719  
 $J_{SC} = 7.87 \text{ mA/cm}^2$   
 $V_{OC} = 750 \text{ mV}$   
 $FF = 0.490$   
 Efficiency = 2.90 %

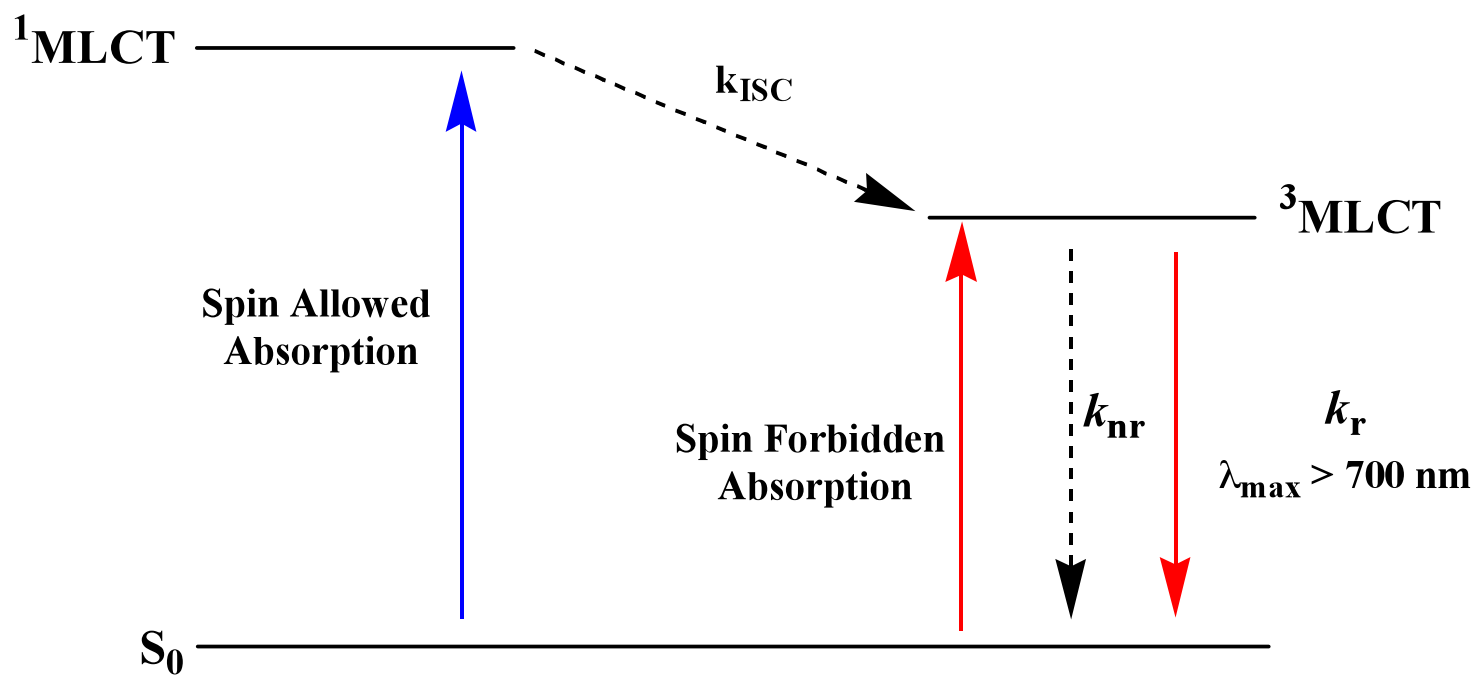
Gopal, K. M. *et. al. NanoLetters* **2006**, 6, 215-218



Dye: D205  
 $J_{SC} = 8.99 \text{ mA/cm}^2$   
 $V_{OC} = 709 \text{ mV}$   
 $FF = 0.561$   
 Efficiency = 3.58 %

Kuang, D. *et. al. ACS Nano* **2008**, 2, 1113-1116

# Jablonski Diagram for Os<sup>II</sup> MLCT Complexes



Can the  $S_0 \rightarrow T_1$  transition be manipulated with variation in  $\pi$ -conjugation in the imine ligand?

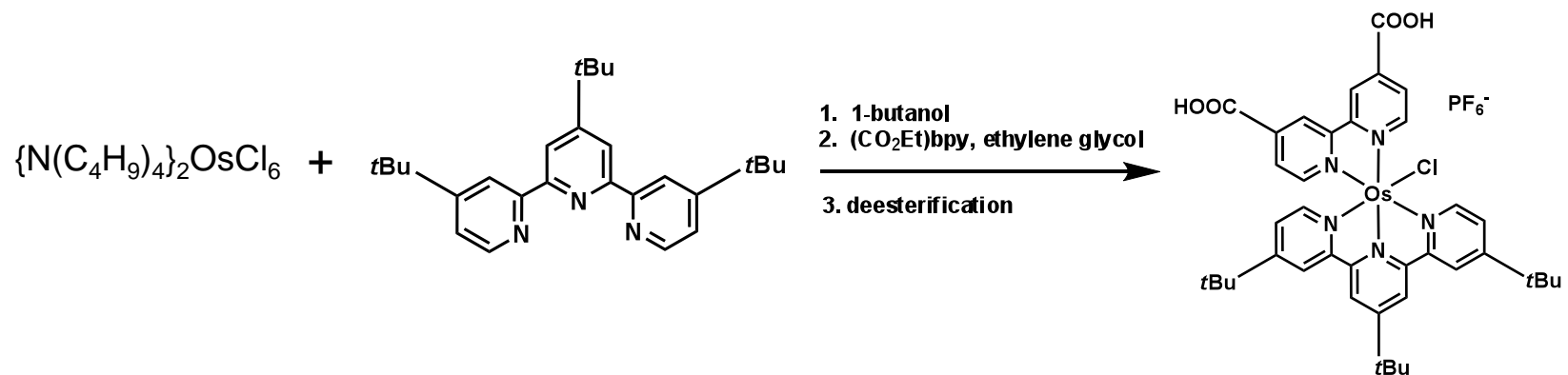
# Advantages of Os<sup>II</sup> over Ru<sup>II</sup>

- Larger value of  $\Delta_o$ , which leads to higher energies for d-d (MC) excited states (no thermal activation)
- Greater extension of the metal *d*-orbitals which can enhance metal - ligand  $\sigma$ -bonding (and  $\pi$ -backbonding)
- Large value of the spin-orbit coupling constant greatly relaxes spin selection rules
- Red to near-IR absorption profiles
- Os<sup>II</sup> MLCT complexes more photochemically/thermally stable relative to those based on Ru<sup>II</sup>

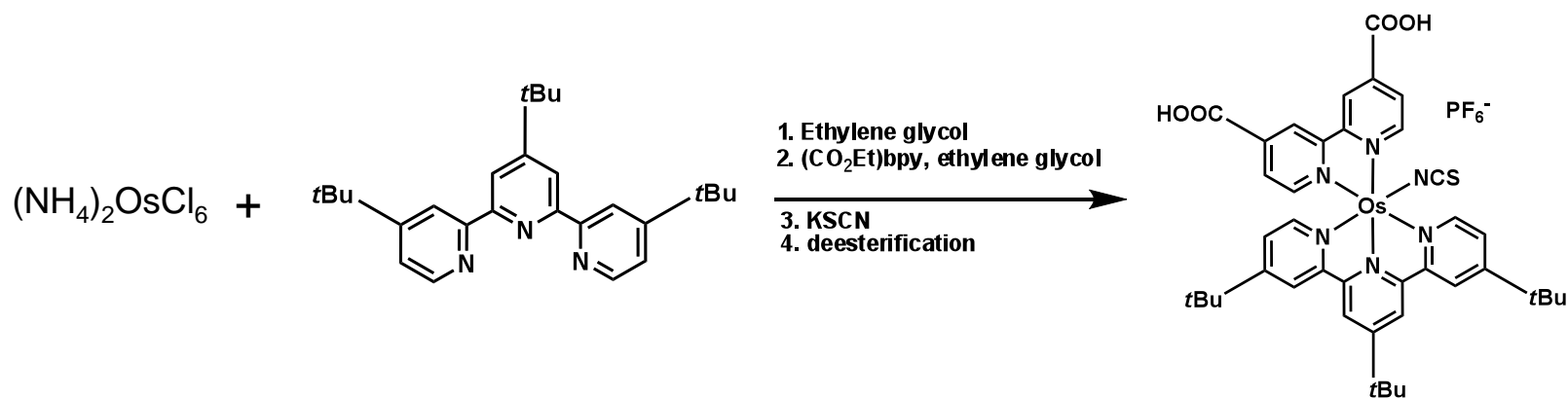
1. Kober, E. M. *et. al. Inorg. Chem.* **1988**, 27, 4587-4598

2. Kalyanasundaram, K. *Photochemistry of polypyridine and porphyrin complexes*; San Diego: California, **1992**.

# Synthesis of Os<sup>II</sup> Dyes of Mixed Denticity

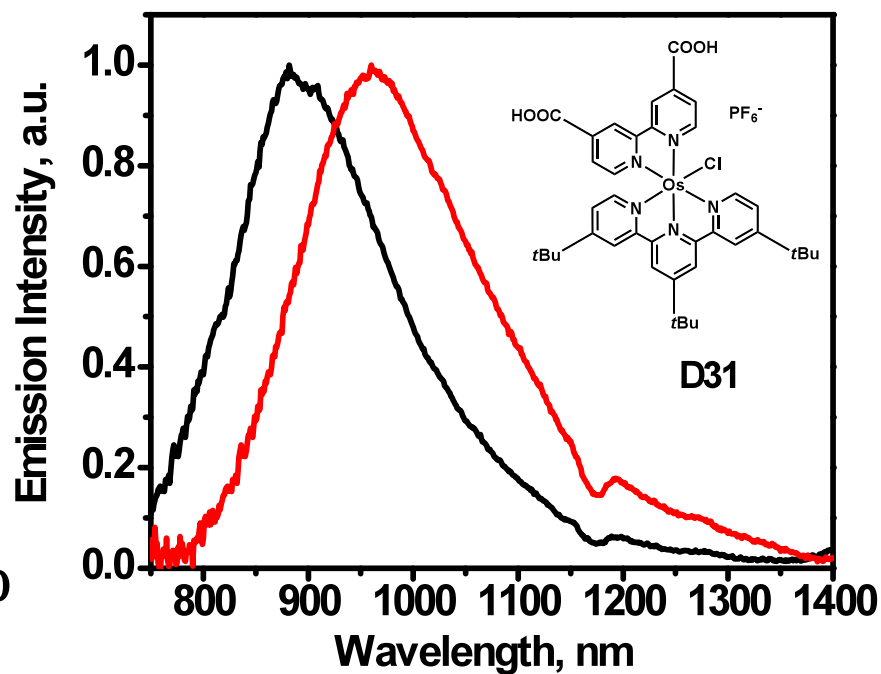
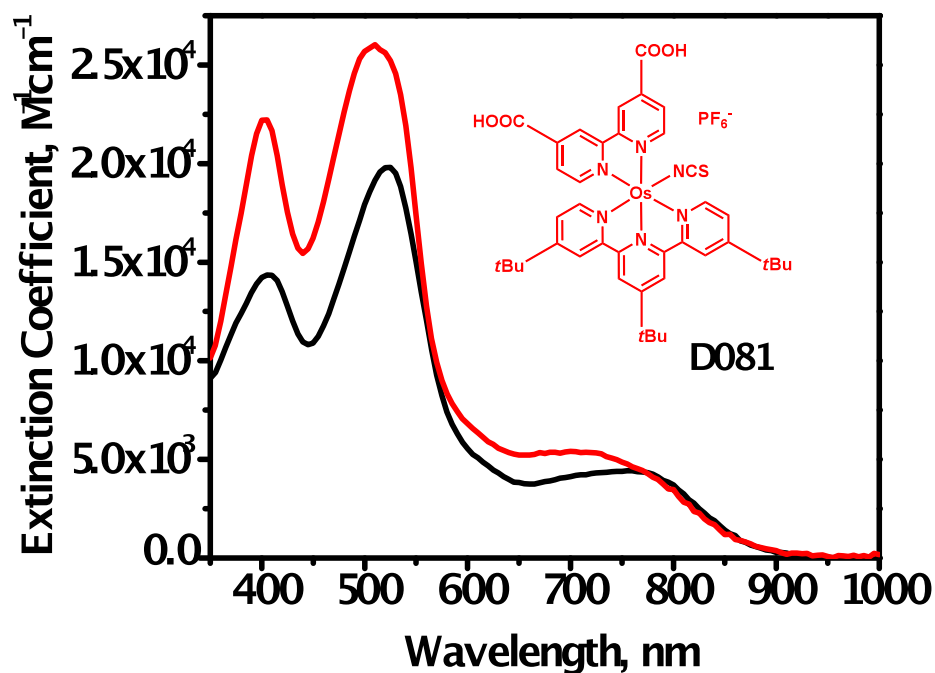


**D31**



**D081**

# Os<sup>II</sup> Dyes: Photophysics and Electrochemistry



†

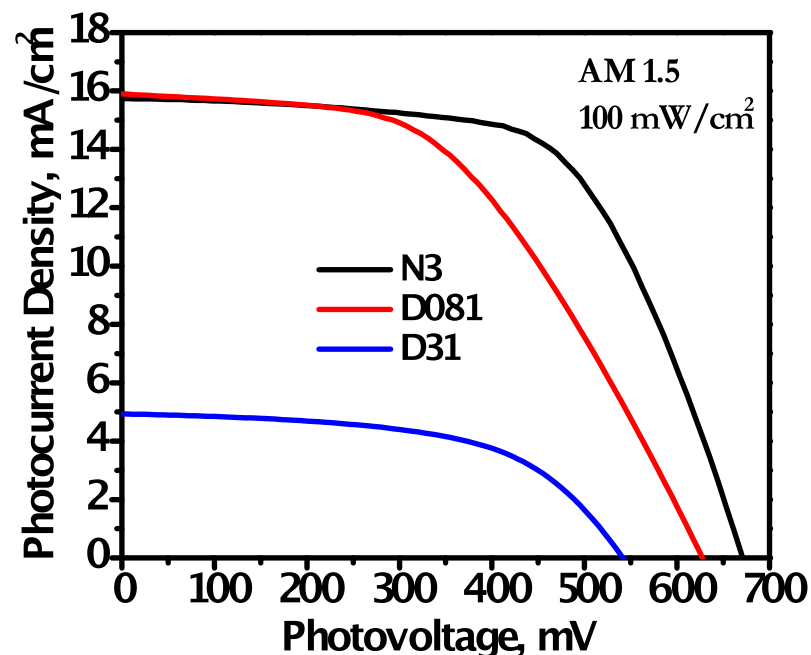
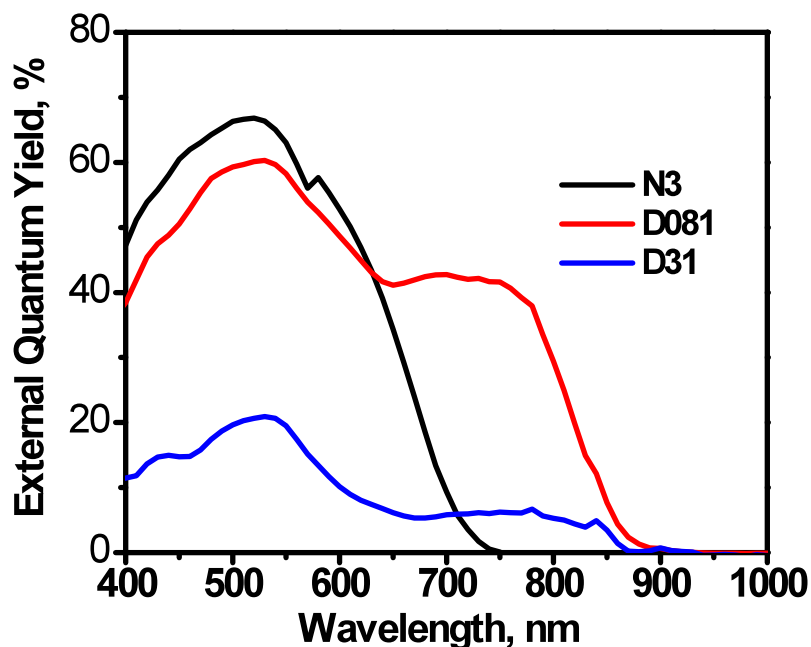
Compound	Absorption max, nm ( $\epsilon \times 10^4, \text{M}^{-1} \text{cm}^{-1}$ )	Emission max, nm	$E_{1/2}$ , V vs NHE <sup>a</sup>
D31	405 (1.44), 525 (1.98), 760 (0.44)	890	0.74 <sup>b</sup>
D081	405 (2.22), 510 (2.60), 700 (0.54)	960	0.88
N3 <sup>c</sup>	313 (3.12), 396 (1.40), 534 (1.42)	755	1.09
<i>t</i> /I <sub>3</sub> <sup>-</sup>			0.4 <sup>d</sup>

<sup>a</sup> In CH<sub>3</sub>CN solution with 0.1 M TBA(PF<sub>6</sub>) as supporting electrolyte and determined by CV; <sup>b</sup> Determined by DPV;

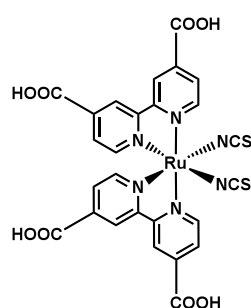
<sup>c</sup> taken from *J. Am. Chem. Soc.* **1993**, *115*, 6382 – 6390; <sup>d</sup> taken from *Adv. Funct. Mater.* **2008**, *18*, 341 – 346.



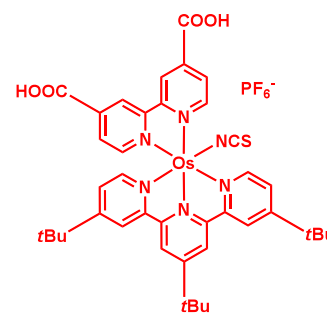
# Os<sup>II</sup> Dyes: Photovoltaic Performance



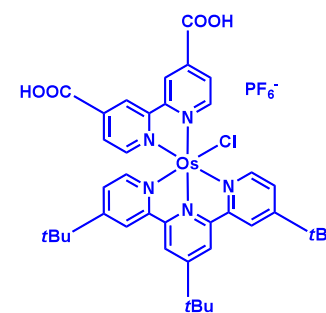
Parameter	N3	D081	D31
$J_{sc}$ , mA/cm <sup>2</sup>	15.7	15.9	4.94
$V_{oc}$ , mV	671	627	542
FF, %	61.7	49.5	56.2
$\eta$ , %	6.52	4.94	1.50



N3



D081

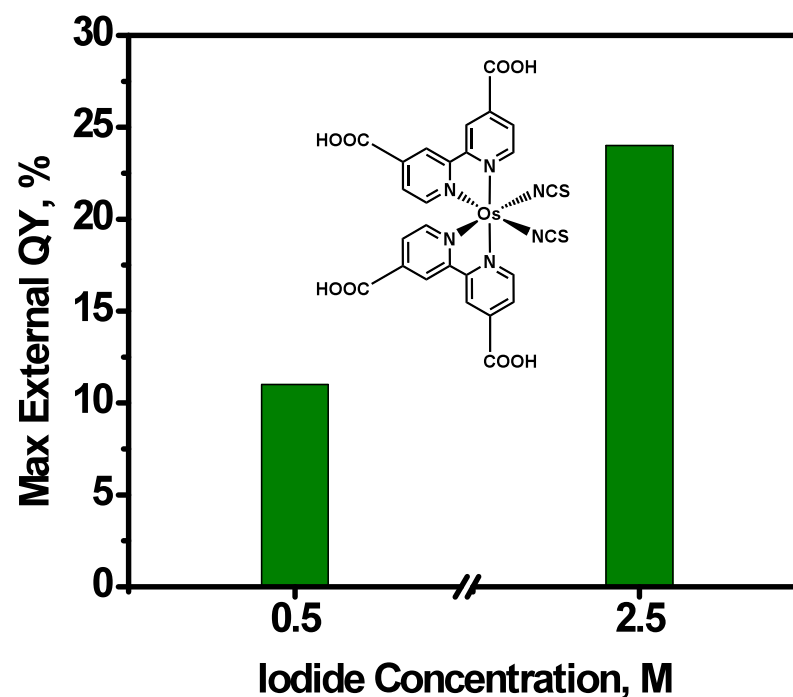
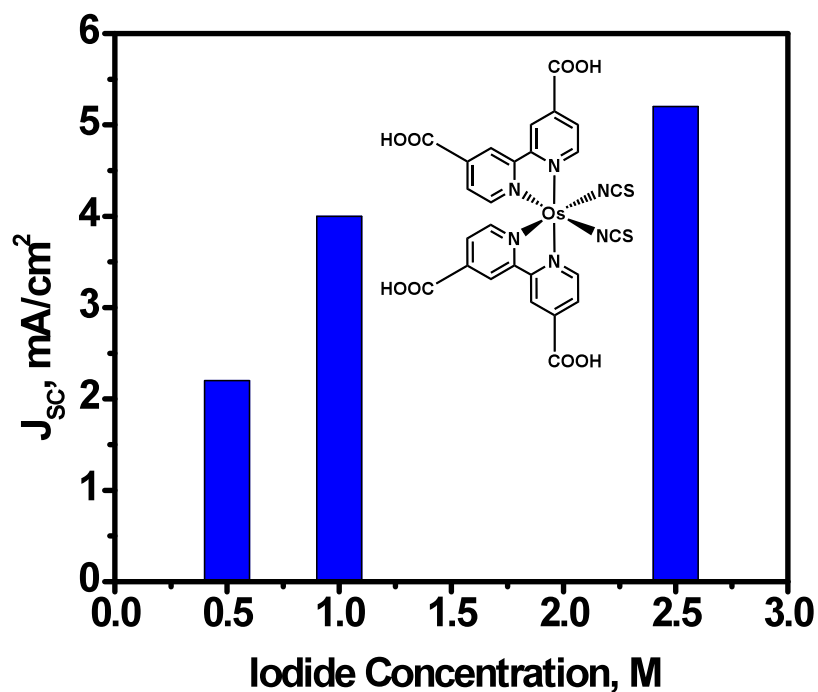


D31

**Electrolyte:** 0.1 M LiI, 0.05 M I<sub>2</sub>, 0.6 M 1-methyl-3-*n*-propylimidazolium iodide, 0.1 M guanidine thiocyanate, 0.5 M 4-*tert*-butylpyridine in CH<sub>3</sub>CN

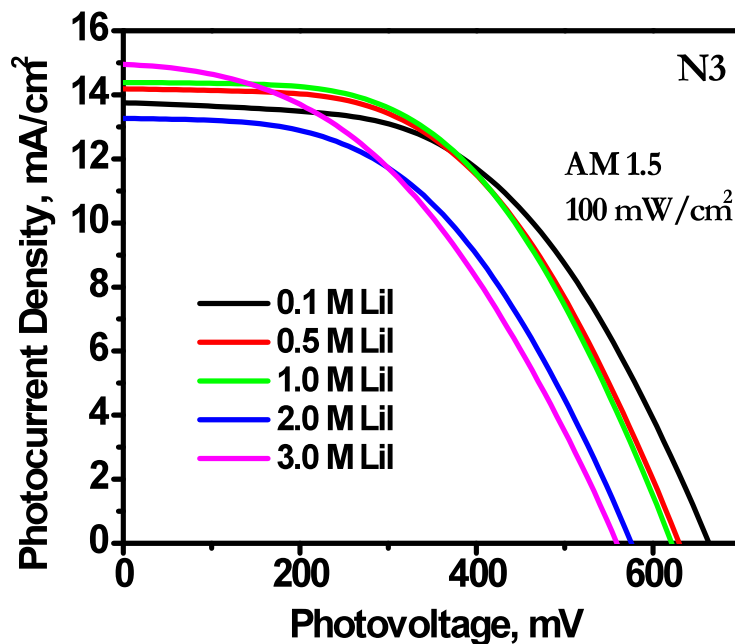
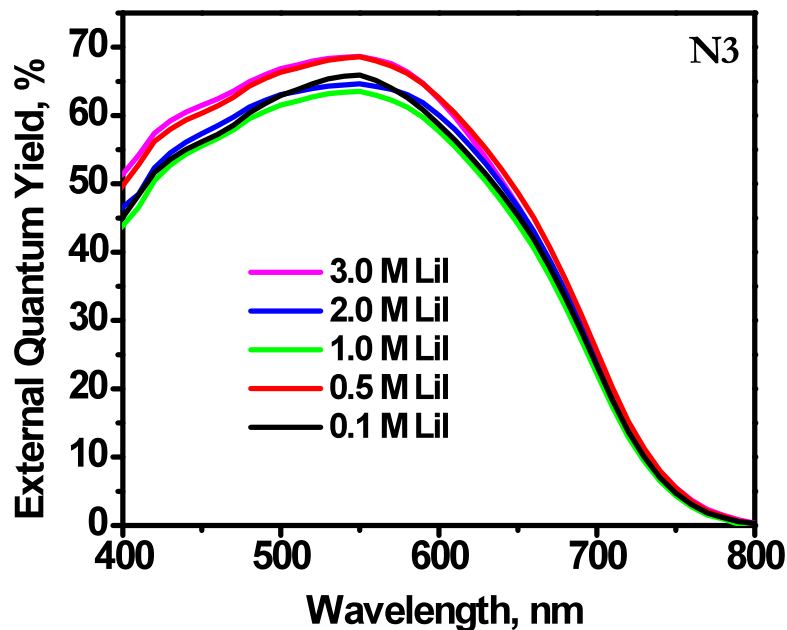
**Device active area:** 0.16 cm<sup>2</sup> (N3), 0.25 cm<sup>2</sup> (D081/D31), TiO<sub>2</sub> film thickness: 12 μm. Transparent paste only. No TiCl<sub>4</sub> for N3; D081/D31 - TiCl<sub>4</sub> treated. Films sintered at 500°C for 30 min., sensitized 48 hrs.

# Influence of Iodide Concentration on the PV Performance of Os<sup>II</sup>: Dye Regeneration Limited



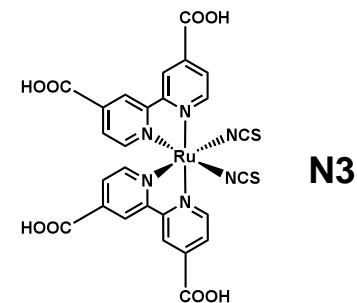
- $J_{SC}$  increased from 2.2 to 5.2 mA/cm<sup>2</sup> upon 5-fold increase in LiI concentration.
- Net effect was attributed to the increase in iodide concentration (LiI + LiClO<sub>4</sub>).
- However, no significant increase in  $J_{SC}$  was observed for corresponding Ru<sup>II</sup> dyes.

# Influence of Lithium Iodide Concentration in N3: [Li<sup>+</sup>] Lowers CB Edge Decreasing V<sub>oc</sub>



∴

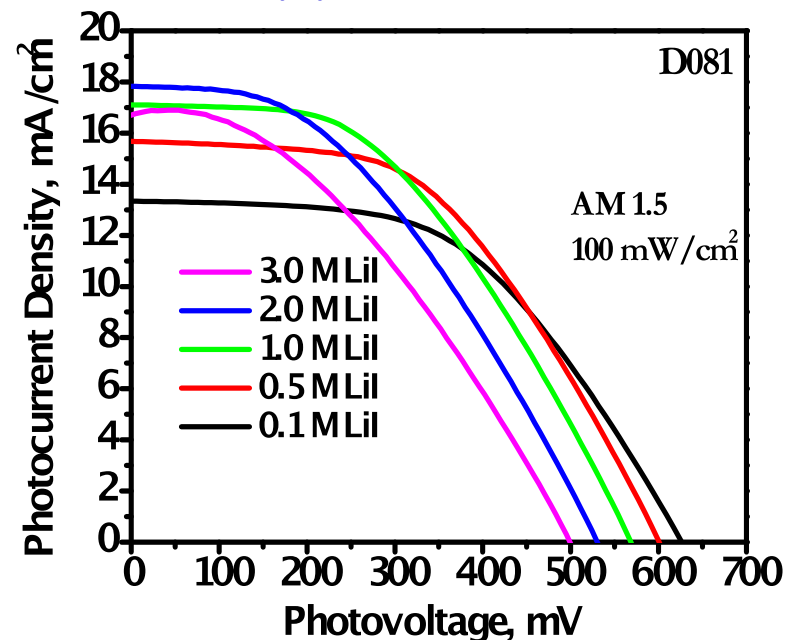
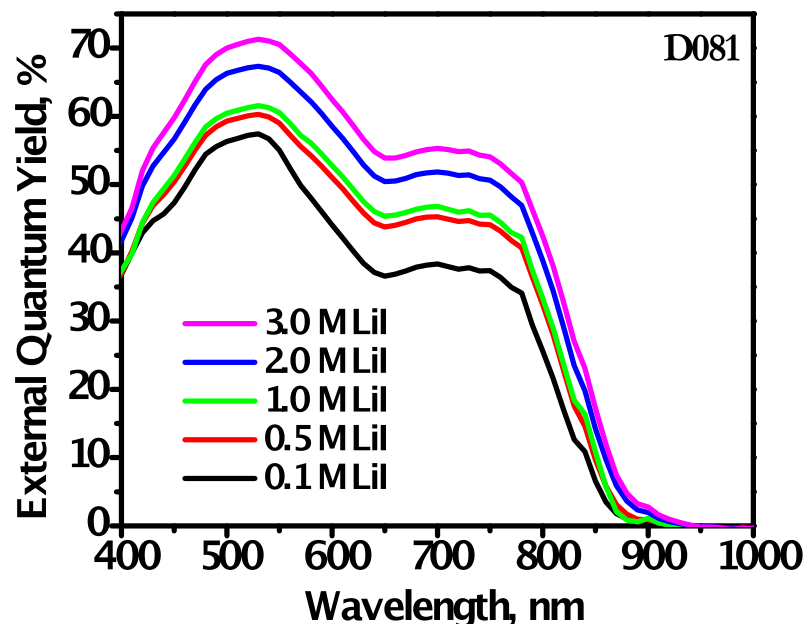
N3	0.1 M LiI	0.5 M LiI	1.0 M LiI	2.0 M LiI	3.0 M LiI
J <sub>sc</sub> , mA/cm <sup>2</sup>	13.8	14.2	14.4	13.3	15.0
V <sub>oc</sub> , mV	664	630	621	576	559
FF, %	51.8	51.5	51.7	48.7	42.8
η, %	4.73	4.60	4.61	3.72	3.58



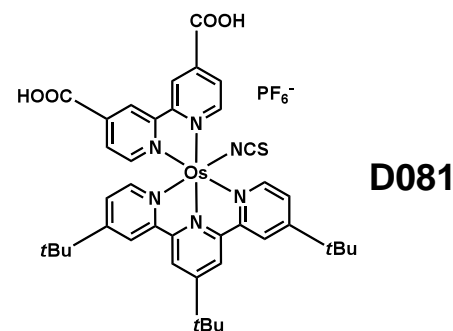
**Electrolyte:** 0.1 M LiI, 0.05 M I<sub>2</sub>, 0.6 M 1-methyl-3-*n*-propylimidazolium iodide, 0.1 M guanidine thiocyanate, 0.5 M 4-*tert*-butylpyridine in CH<sub>3</sub>CN. LiI concentration was varied as shown.

**Device active area:** 0.25 cm<sup>2</sup>. TiCl<sub>4</sub> treatment for all slides. Films sintered at 500°C for 30 min., sensitized 48 hrs. TiO<sub>2</sub> film thickness: 12 μm. Transparent paste only.

# Influence of Lithium Iodide Concentration in D081: A Combination of Both Effects?



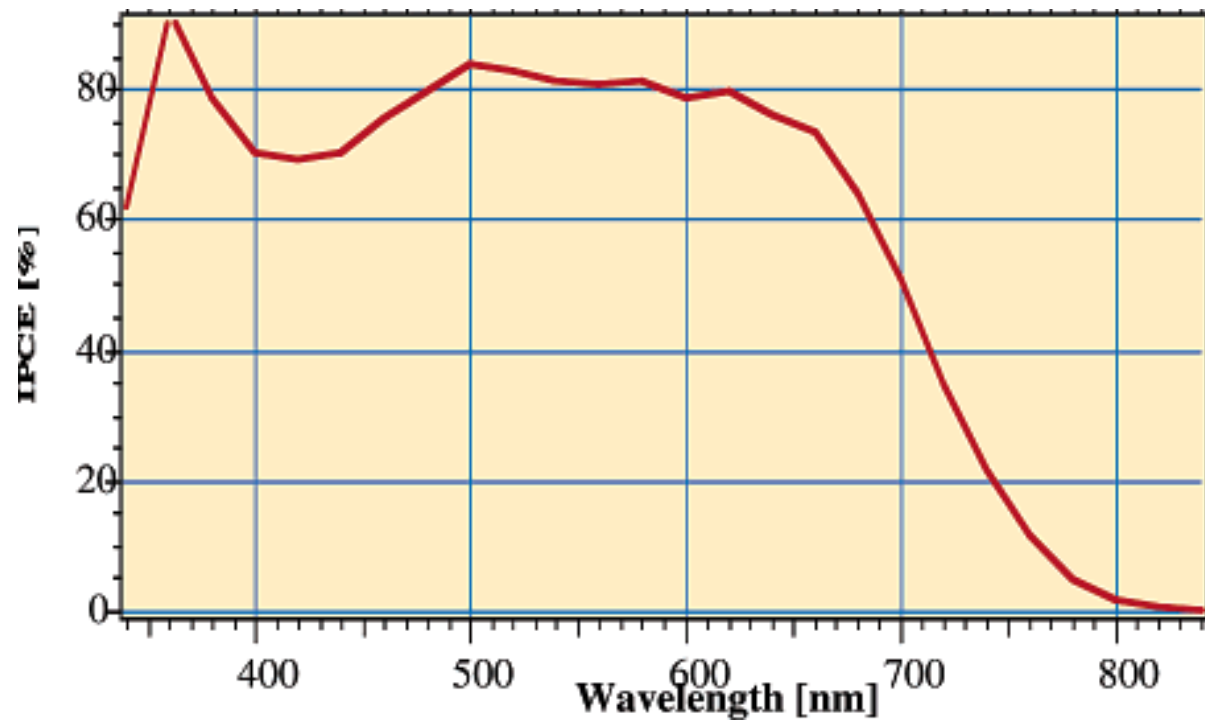
D081	0.1 M LiI	0.5 M LiI	1.0 M LiI	2.0 M LiI	3.0 M LiI
$J_{sc}$ , mA/cm <sup>2</sup>	13.3	15.7	17.1	17.8	16.7
$V_{oc}$ , mV	626	601	569	530	499
FF, %	52.0	50.1	46.0	41.5	38.9
$\eta$ , %	4.34	4.72	4.48	3.92	3.24

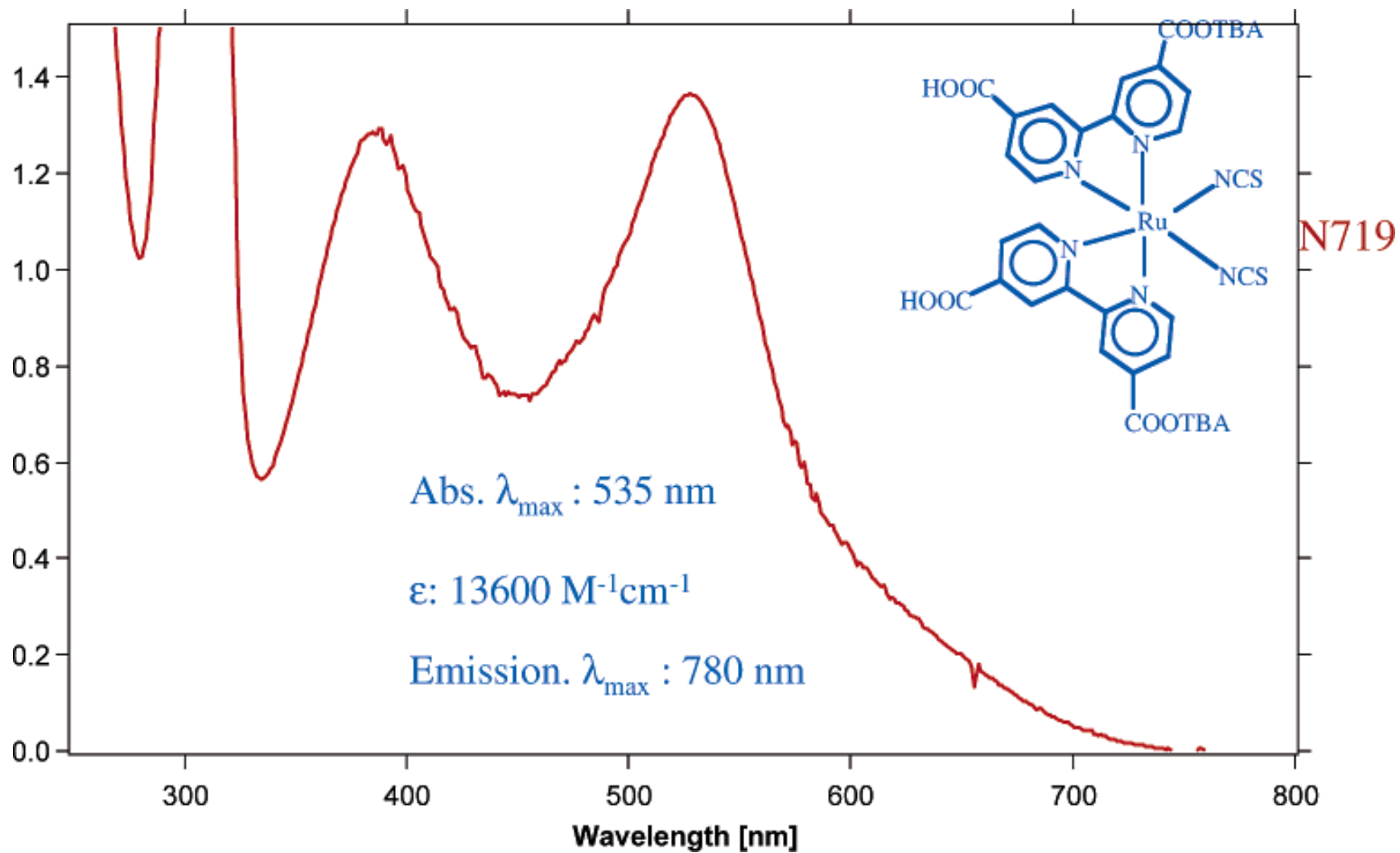


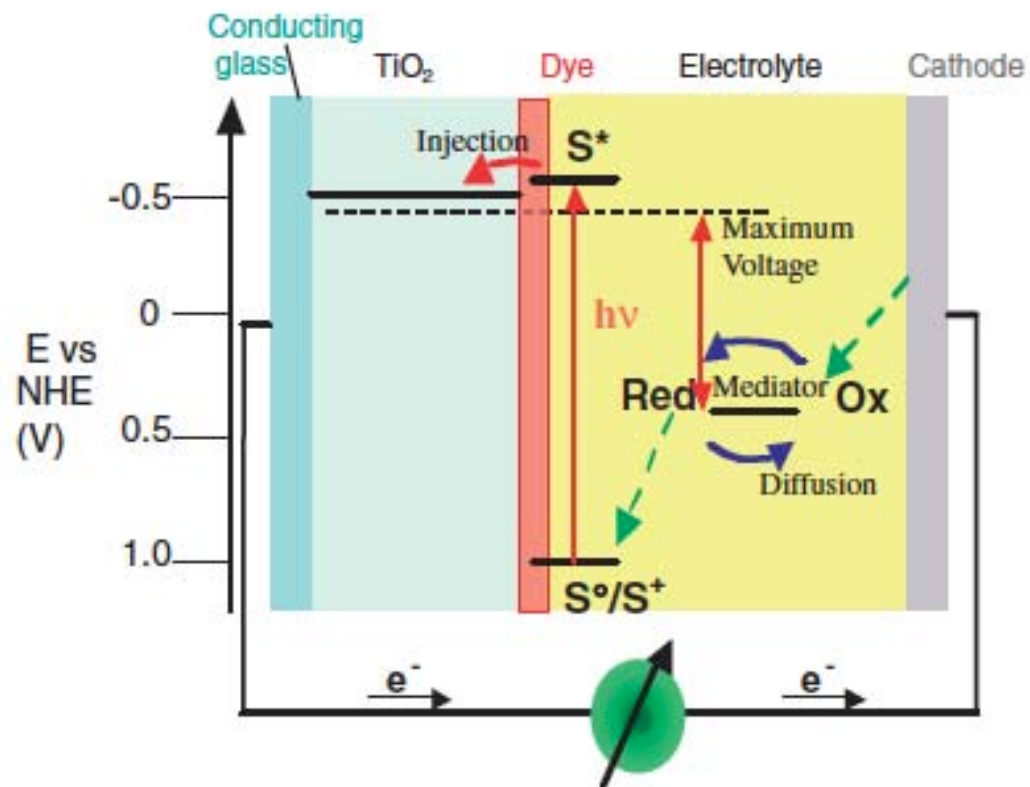
**Electrolyte:** 0.1 M LiI, 0.05 M I<sub>2</sub>, 0.6 M 1-methyl-3-*n*-propylimidazolium iodide, 0.1 M guanidine thiocyanate, 0.5 M 4-*tert*-butylpyridine in CH<sub>3</sub>CN. LiI concentration was varied as shown.

**Device active area:** 0.25 cm<sup>2</sup>. TiCl<sub>4</sub> treatment for all slides. Films sintered at 500°C for 30 min., sensitized 48 hrs. TiO<sub>2</sub> film thickness: 12 μm. Transparent paste only.

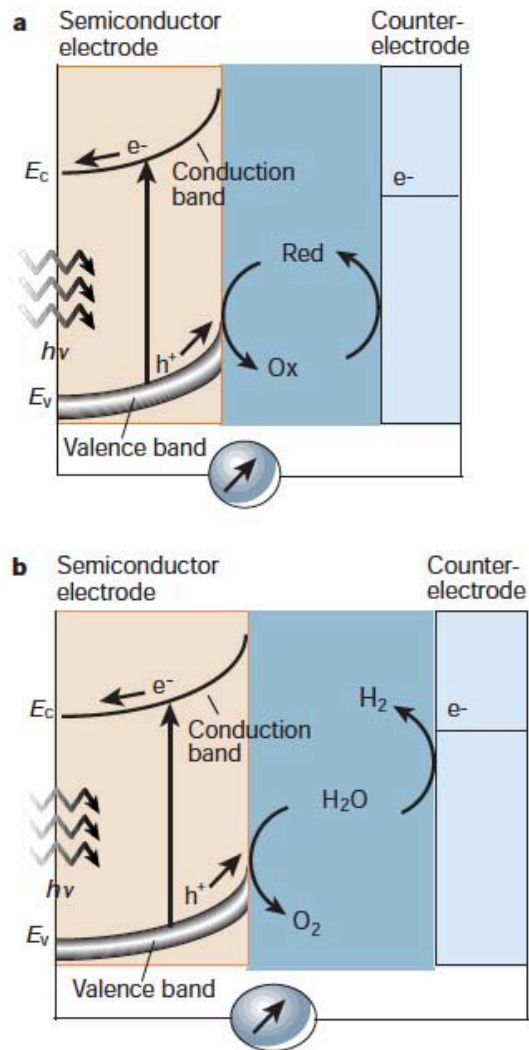
**Questions?**



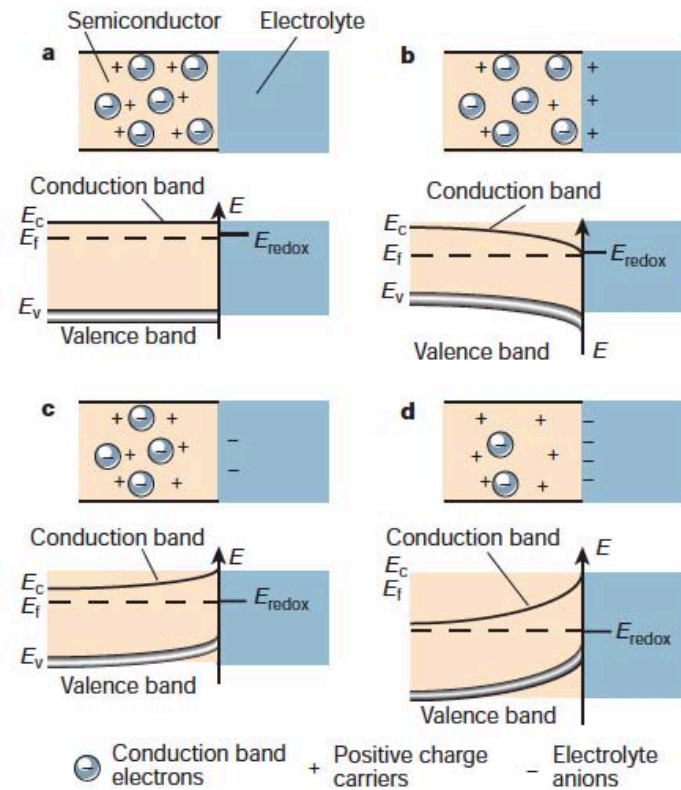








**Figure 1** Principle of operation of photoelectrochemical cells based on *n*-type semiconductors. **a**, Regenerative-type cell producing electric current from sunlight; **b**, a cell that generates a chemical fuel, hydrogen, through the photo-cleavage of water.



**Box 1 Figure** Schematic showing the electronic energy levels at the interface between an *n*-type semiconductor and an electrolyte containing a redox couple. The four cases indicated are: **a**, flat band potential, where no space-charge layer exists in the semiconductor; **b**, accumulation layer, where excess electrons have been injected into the solid producing a downward bending of the conduction and valence band towards the interface; **c**, depletion layer, where electrons have moved from the semiconductor to the electrolyte, producing an upward bending of the bands; and **d**, inversion layer where the electrons have been depleted below their intrinsic level, enhancing the upward band bending and rendering the semiconductor *p*-type at the surface.

